

## 22-V Input, 12-A Integrated FET Converter With Ultra-Low Quiescent (ULQ™)

Check for Samples: [TPS51367](#)

### FEATURES

- Input Voltage Range: 3 V to 22 V
- Output Voltage Range: 0.6 V to 2 V
- 12-A Integrated FET Converter
- Fewest External Components
- **ULQ™-100 Mode of Operation to Enable Long Battery Life During System Standby**
- **Soft-Start Time Programmable by External Capacitor**
- **Switching Frequency: 400 kHz and 800 kHz**
- **D-CAP2™ Architecture to Enable POSCAP and All MLCC Output Capacitor Usage**
- **Integrated and Temperature Compensated Low-Side On-Resistance Sensing for Accurate OCL Protection**
- **Powergood Output**  
OCL, OVP, UVP and UVLO Protections
- **Thermal Shutdown (non-latch)**
- **Output Discharge Function**
- **Integrated Boost MOSFET Switch**
- **28-Pin, 3.5-mm × 4.5-mm, RVE, QFN Package with 0.4-mm Pitch and 1-mm Height**

### APPLICATIONS

- **Notebook Computers (VCCIO)**
- **Memory Rails (DDR VDDQ)**

### DESCRIPTION

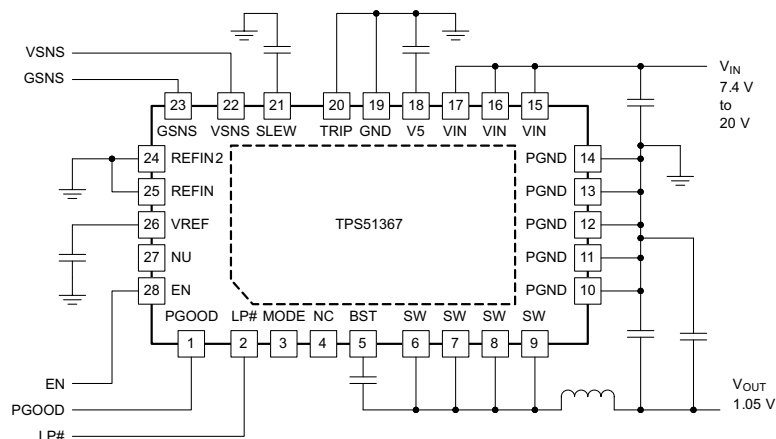
The TPS51367 is a high-voltage input, synchronous converter with integrated FET, based on DCAP-2™ control topology, which enables fast transient response and supports both POSCAP and all MLCC output capacitors. TI proprietary FET technology combined with TI leading-edge package technology provides the highest density solution for single-output power rail such as VCCIO and VDDQ for DDR notebook memory, or any point-of-load (POL) in wide application.

The key feature of the TPS51367 is its ULQ™ Mode to enable low-bias current (100  $\mu$ A in low power mode, enabled by LP#). This feature is extremely beneficial for long battery life in system standby mode.

The feature set includes switching frequency of 800 kHz. Programmable soft-start time with an external capacitor. auto skip, pre-bias startup, integrated bootstrap switch, power good, enable and a full suite of fault protection schemes, including OCL, UVP, OVP, 5-V UVLO and thermal shutdown.

It is packaged in 3.5 mm × 4.5 mm, 0.4-mm pitch, 28-pin QFN (RVE), and specified from -10°C to 85°C.

### SIMPLIFIED APPLICATION



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

### ORDERING INFORMATION<sup>(1)</sup> (2)

| T <sub>A</sub> | PACKAGE                      | ORDERABLE DEVICE NUMBER | PINS | TRANSPORT MEDIA     | MINIMUM ORDER QUANTITY |
|----------------|------------------------------|-------------------------|------|---------------------|------------------------|
| –10°C to 85°C  | Plastic Quad Flat Pack (QFN) | TPS51367RVET            | 28   | Small tape-and-reel | 250                    |
|                |                              | TPS51367RVER            |      | Large tape-and-reel | 3000                   |

- (1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or visit the TI website at [www.ti.com](http://www.ti.com).
- (2) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at [www.ti.com/sc/package](http://www.ti.com/sc/package).

### ABSOLUTE MAXIMUM RATINGS<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

|                                             |                                                          |                  | VALUE |      | UNIT |
|---------------------------------------------|----------------------------------------------------------|------------------|-------|------|------|
|                                             |                                                          |                  | MIN   | MAX  |      |
| Input voltage range <sup>(2)</sup>          | VIN                                                      |                  | −0.3  | 30   | V    |
|                                             | BST                                                      |                  |       | 36   |      |
|                                             |                                                          | transient <10 ns |       | 38   |      |
|                                             |                                                          | w/r/t SW         |       | 6    |      |
|                                             | SW                                                       |                  |       | 30   |      |
|                                             | EN, TRIP, NU, MODE, V5, LP#                              |                  | −0.3  | 6    |      |
|                                             | SLEW, VSNS, REFIN, REFIN2                                |                  | −0.3  | 3.6  |      |
|                                             | GSNS                                                     |                  | −0.35 | 0.35 |      |
|                                             | PGND                                                     |                  | −0.3  | 0.3  |      |
| Output voltage range <sup>(2)</sup>         | PGOOD                                                    |                  | −0.3  | 6    | V    |
|                                             | VREF                                                     |                  | −0.3  | 3.6  |      |
|                                             | NC                                                       |                  | −5    | 36   |      |
| Electrostatic discharge                     | Human body model (HBM) QSS 009-105 (JESD22-A114A)        |                  |       | 2000 | V    |
|                                             | Charged device model (CDM) QSS 009-147 (JESD22-C101B.01) |                  |       | 500  |      |
| Junction temperature range, T <sub>J</sub>  |                                                          |                  | −10   | 150  | °C   |
| Storage temperature range, T <sub>stg</sub> |                                                          |                  | −55   | 150  |      |

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values are with respect to the network ground terminal unless otherwise noted.

## THERMAL INFORMATION

| THERMAL METRIC <sup>(1)</sup> |                                              | TPS51367               | UNITS |
|-------------------------------|----------------------------------------------|------------------------|-------|
|                               |                                              | QFN (RVE)<br>(28 PINS) |       |
| $\theta_{JA}$                 | Junction-to-ambient thermal resistance       | 40.2                   | °C/W  |
| $\theta_{JCTop}$              | Junction-to-case (top) thermal resistance    | 22.8                   |       |
| $\theta_{JB}$                 | Junction-to-board thermal resistance         | 20.1                   |       |
| $\Psi_{JT}$                   | Junction-to-top characterization parameter   | 1.6                    |       |
| $\Psi_{JB}$                   | Junction-to-board characterization parameter | 19.4                   |       |
| $\theta_{JCbott}$             | Junction-to-case (bottom) thermal resistance | 2.2                    |       |

(1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, [SPRA953](#).

## RECOMMENDED OPERATING CONDITIONS

over operating free-air temperature range (unless otherwise noted)

|                                                |                           | MIN  | MAX  | UNIT |
|------------------------------------------------|---------------------------|------|------|------|
| Supply voltage range                           | VIN                       | 3    | 22   | V    |
|                                                | V5                        | 4.6  | 5.5  |      |
| Input voltage range                            | BST                       | −0.1 | 33.5 |      |
|                                                | SW                        | −3   | 27   |      |
|                                                | EN, TRIP, NU, MODE, LP#   | −0.1 | 5.5  |      |
|                                                | SLEW, VSNS, REFIN, REFIN2 | −0.1 | 3.5  |      |
|                                                | GSNS                      | −0.1 | 0.3  |      |
|                                                | PGND                      | −0.1 | 0.1  |      |
| Output voltage range                           | PGOOD                     | −0.1 | 5.5  |      |
|                                                | VREF, SLEW                | −0.1 | 3.5  |      |
| Operating free-air temperature, T <sub>A</sub> |                           | −10  | 85   | °C   |

## ELECTRICAL CHARACTERISTICS

over operating free-air temperature range,  $V_{IN} = 12\text{ V}$ ,  $V_{V5} = 5\text{ V}$ ,  $\text{MODE} = \text{GND}$ ,  $V_{EN} = 3.3\text{ V}$  (unless otherwise noted)

| PARAMETER                                           | TEST CONDITION                                                                                                        | MIN  | TYP  | MAX  | UNIT             |
|-----------------------------------------------------|-----------------------------------------------------------------------------------------------------------------------|------|------|------|------------------|
| <b>SUPPLY CURRENT</b>                               |                                                                                                                       |      |      |      |                  |
| $I_{V5}$ V5 supply current                          | $T_A = 25^\circ\text{C}$ , No load, $V_{EN} = 5\text{ V}$ , $\text{LP\#} = 0\text{ V}$                                |      | 100  |      | $\mu\text{A}$    |
|                                                     | $T_A = 25^\circ\text{C}$ , No load, $V_{EN} = 5\text{ V}$                                                             |      | 560  |      |                  |
| $I_{V5\text{SDN}}$ V5 shutdown current              | $T_A = 25^\circ\text{C}$ , No load, $V_{EN} = 0\text{ V}$                                                             |      | 1    |      | $\mu\text{A}$    |
| <b>VREF OUTPUT</b>                                  |                                                                                                                       |      |      |      |                  |
| $V_{VREF}$ Reference voltage                        | $I_{VREF} = 30\text{ }\mu\text{A}$ , w.r.t. GSNS                                                                      |      | 2    |      | V                |
|                                                     | $0\text{ }\mu\text{A} \leq I_{VREF} \leq 300\text{ }\mu\text{A}$ , $-10^\circ\text{C} \leq T_A \leq 85^\circ\text{C}$ | -1%  |      | 1%   |                  |
| $I_{VREF(\text{OCL})}$ Current limit                | $(V_{VREF} - V_{GSNS}) = 1.7\text{ V}$                                                                                | 0.4  | 1    |      | $\text{mA}$      |
| <b>VOLTAGE AMPLIFIER</b>                            |                                                                                                                       |      |      |      |                  |
| $I_{VSNS}$ VSNS input current                       | $V_{VSNS} = 1\text{ V}$                                                                                               | -1   |      | 1    | $\mu\text{A}$    |
| $I_{VSNS(\text{DIS})}$ VSNS discharge current       | $V_{EN} = 0\text{ V}$ , $V_{VSNS} = 0.5\text{ V}$                                                                     |      | 12   |      | $\text{mA}$      |
| <b>SMPS FREQUENCY</b>                               |                                                                                                                       |      |      |      |                  |
| $t_{\text{OFF}(\text{min})}$ Minimum off-time       |                                                                                                                       |      | 320  |      | ns               |
| $t_{\text{DEAD1}}$ Deadtime1 <sup>(1)</sup>         | SW rising to falling                                                                                                  |      | 10   |      | ns               |
| $t_{\text{DEAD2}}$ Deadtime2 <sup>(1)</sup>         | SW falling to rising                                                                                                  |      | 10   |      | ns               |
| <b>INTERNAL BOOT STRAP SW</b>                       |                                                                                                                       |      |      |      |                  |
| $V_{\text{FBST}}$ Forward foltage                   | $V_{V5} - B_{\text{ST}}$ , $T_A = 25^\circ\text{C}$ , $I_F = 10\text{ mA}$                                            |      | 0.1  | 0.2  | V                |
| $I_{\text{BST}}$ BST leakage current                | $T_A = 25^\circ\text{C}$ , $V_{\text{BST}} = 14\text{ V}$ , $V_{\text{SW}} = 7\text{ V}$                              |      | 0.01 | 1.5  | $\mu\text{A}$    |
| <b>MOSFET ON-RESISTANCE</b>                         |                                                                                                                       |      |      |      |                  |
| $R_{\text{DS(on)H}}$ High-side on-resistance        | $T_A = 25^\circ\text{C}$ , $V_{V5} = 5\text{ V}$                                                                      |      |      | 15   | $\text{m}\Omega$ |
| $R_{\text{DS(on)L}}$ Low-side on-resistance         | $T_A = 25^\circ\text{C}$ , $V_{V5} = 5\text{ V}$                                                                      |      |      | 7.5  | $\text{m}\Omega$ |
| <b>LOGIC THRESHOLD</b>                              |                                                                                                                       |      |      |      |                  |
| $V_{\text{MODE}(\text{TH})}$ MODE threshold voltage | MODE = FLOAT                                                                                                          |      | 2.5  |      | V                |
| $V_{\text{LL}}$ EN low-level voltage                |                                                                                                                       |      |      | 0.35 | V                |
| $V_{\text{LH}}$ EN high-level voltage               |                                                                                                                       | 0.9  |      |      | V                |
| $V_{\text{L}(\text{HYST})}$ EN hysteresis voltage   |                                                                                                                       |      | 0.25 |      | V                |
| $V_{\text{L}(\text{LK})}$ EN input leakage current  |                                                                                                                       | -1   | 0    | 1    | $\mu\text{A}$    |
| $V_{\text{LL}}$ LP# low-level voltage               |                                                                                                                       |      |      | 0.35 | V                |
| $V_{\text{LH}}$ LP# high-level voltage              |                                                                                                                       | 0.85 |      |      | V                |
| $V_{\text{L}(\text{HYST})}$ LP# hysteresis voltage  |                                                                                                                       |      | 0.4  |      | V                |
| $V_{\text{L}(\text{LK})}$ LP# input leakage current |                                                                                                                       | -1   | 0    | 1    | $\mu\text{A}$    |
| <b>SOFT-START</b>                                   |                                                                                                                       |      |      |      |                  |
| $I_{\text{SS}}$ Soft-Start current                  | Soft-start current source                                                                                             |      | 10   |      | $\mu\text{A}$    |
| <b>PGOOD COMPARATOR</b>                             |                                                                                                                       |      |      |      |                  |
| $V_{\text{PGTH}}$ PGOOD threshold                   | PGOOD in from lower (startup)                                                                                         |      | 92%  |      |                  |
| $I_{\text{PG}}$ PGOOD sink current                  | $V_{\text{PGOOD}} = 0.5\text{ V}$                                                                                     |      | 6    |      | $\text{mA}$      |
| $t_{\text{PG}(\text{CMPSS})}$ PGOOD start-up delay  | PGOOD comparator startup delay                                                                                        |      | 1.5  |      | ms               |
| $I_{\text{PG}(\text{LK})}$ PGOOD leakage current    |                                                                                                                       | -1   | 0    | 1    | $\mu\text{A}$    |

(1) Ensured by design.

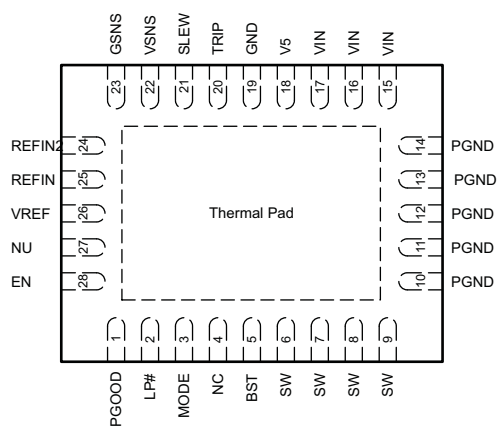


## ELECTRICAL CHARACTERISTICS (continued)

over operating free-air temperature range,  $V_{IN} = 12\text{ V}$ ,  $V_{V5} = 5\text{ V}$ ,  $MODE = GND$ ,  $V_{EN} = 3.3\text{ V}$  (unless otherwise noted)

| PARAMETER                      |                                                    | TEST CONDITION                                                                 | MIN    | TYP  | MAX    | UNIT             |
|--------------------------------|----------------------------------------------------|--------------------------------------------------------------------------------|--------|------|--------|------------------|
| <b>OVERCURRENT LIMIT LEVEL</b> |                                                    |                                                                                |        |      |        |                  |
| $I_{OCL}$                      | Current limit threshold                            | $V_{TRIP} = 0\text{ V}$ , valley current set point, $T_A = 25^\circ\text{C}$   | 7      | 8    | 9      | A                |
|                                |                                                    | $V_{TRIP} = 5\text{ V}$ , valley current set point, $T_A = 25^\circ\text{C}$   | 10.5   | 12.0 | 13.5   |                  |
|                                |                                                    | $V_{TRIP} = \text{FLOAT}$ , valley current set point, $T_A = 25^\circ\text{C}$ | 14     | 16   | 18     |                  |
| $V_{ZC}^{(2)}$                 | Zero cross detection offset                        |                                                                                |        | 0    |        | mV               |
| <b>PROTECTIONS</b>             |                                                    |                                                                                |        |      |        |                  |
| $V_{POR}$                      | V5 POR threshold voltage <sup>(2)</sup>            | Reset OVP fault                                                                |        | 1.7  |        | V                |
| $V_{PORHYS}$                   | V5 POR threshold voltage hysteresis <sup>(2)</sup> | Reset OVP fault hysteresis                                                     |        | 85   |        | mV               |
| $V_{UVLO}$                     | V5 UVLO threshold voltage                          | Wake-up                                                                        | 4.3    | 4.4  | 4.6    | V                |
|                                |                                                    | Shutdown                                                                       | 3.8    | 4    | 4.2    |                  |
| $V_{OVP}$                      | OVP threshold voltage                              | OVP detect voltage                                                             | 118%   | 120% | 123%   |                  |
| $t_{OVPDLY}$                   | OVP propagation delay                              | With 100 mV overdrive                                                          |        | 430  |        | ns               |
| $V_{OOB}$                      | OOB threshold voltage                              |                                                                                | 105.5% |      | 109.5% |                  |
| $V_{UVP}$                      | UVP threshold voltage                              | UVP detect voltage                                                             | 63%    | 66%  | 69%    |                  |
| $t_{UVPDLY}$                   | UVP delay                                          |                                                                                |        | 1    |        | ms               |
| <b>THERMAL SHUTDOWN</b>        |                                                    |                                                                                |        |      |        |                  |
| $T_{SDN}$                      | Thermal shutdown threshold <sup>(2)</sup>          | Shutdown temperature                                                           |        | 140  |        | $^\circ\text{C}$ |
|                                |                                                    | Hysteresis                                                                     |        | 10   |        |                  |

(2) Ensured by design.

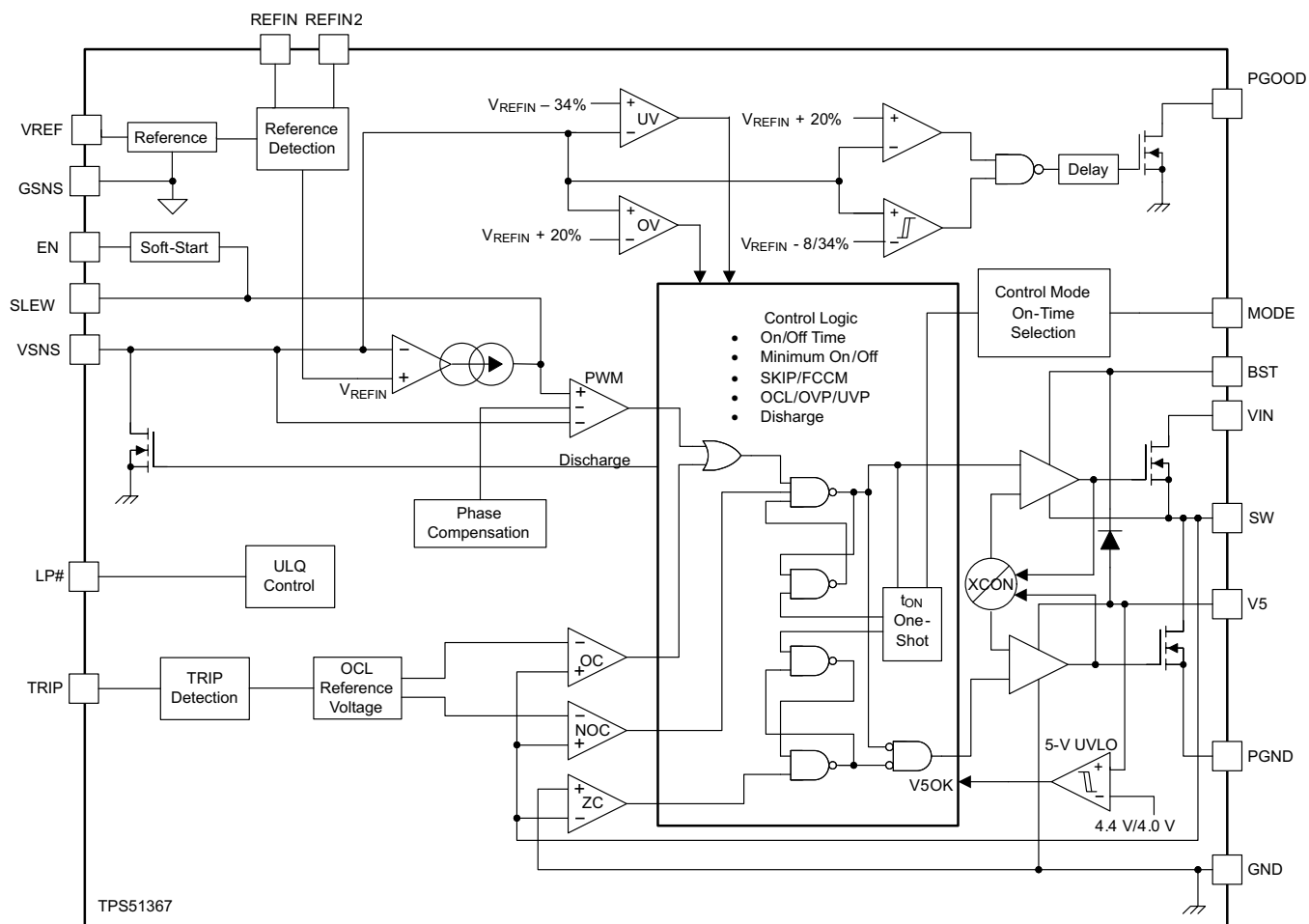
**DEVICE INFORMATION**
**RVE PACKAGE  
28 PINS  
(TOP VIEW)**


### PIN FUNCTIONS

| NAME      | NO. | I/O/P <sup>(1)</sup> | DESCRIPTION                                                                                                         |
|-----------|-----|----------------------|---------------------------------------------------------------------------------------------------------------------|
| BST       | 5   | I                    | Power supply for internal high side MOSFET. Connect a 0.1-μF bootstrap capacitor between this pin and SW pin.       |
| EN        | 28  | I                    | Enable signal, 1.05-V logic compatible.                                                                             |
| GND       | 19  | —                    | General device ground.                                                                                              |
| GSNS      | 23  | O                    | GND sense input. Connect GSNS to general/system ground or GND sensing point at the output return.                   |
| LP#       | 2   | I                    | Low power signal (active low) to indicate the converter entering ULQ™ mode. 1.05-V logic compatible.                |
| MODE      | 3   | I                    | Frequency (400 kHz and 800 kHz) programmable input (see <a href="#">Table 2</a> ).                                  |
| NC        | 4   | —                    | Not connected.                                                                                                      |
| NU        | 27  | —                    | Not used for external applications.                                                                                 |
| PGND      | 10  | —                    | Power ground. Connect to the system ground.                                                                         |
|           | 11  |                      |                                                                                                                     |
|           | 12  |                      |                                                                                                                     |
|           | 13  |                      |                                                                                                                     |
|           | 14  |                      |                                                                                                                     |
| PGOOD     | 1   | O                    | PGOOD output. Connect a pull-up resistor with a value of 100 kΩ to this pin.                                        |
| Power PAD | 29  | —                    | Connect to system ground by multiple vias.                                                                          |
| REFIN     | 25  | I                    | Target output voltage input pin. 0.6 V to 2 V, 1.05 V/1.2 V built-in (GND and Open) (see <a href="#">Table 1</a> ). |
| REFIN2    | 24  | I                    | Tie to GND or FLOAT. This input is used to determine the fixed voltage setpoint (see <a href="#">Table 1</a> ).     |
| SLEW      | 21  | O                    | Connect a capacitor between this pin and GND for soft start and integrator functions.                               |
| SW        | 6   | O                    | Switching node output. Connect external inductor.                                                                   |
|           | 7   |                      |                                                                                                                     |
|           | 8   |                      |                                                                                                                     |
|           | 9   |                      |                                                                                                                     |
| TRIP      | 20  | I                    | OCL programmable input (see <a href="#">Table 3</a> ).                                                              |
| V5        | 18  | I                    | 5-V power supply for analog circuits and gate driver.                                                               |
| VIN       | 15  | I                    | Power supply input pin. Apply 3-V to 22-V of supply voltage.                                                        |
|           | 16  | I                    |                                                                                                                     |
|           | 17  | I                    |                                                                                                                     |
| VREF      | 26  | O                    | 2-V reference output. Connect a 0.1-μF ceramic capacitor between this pin and the GNDS pin.                         |
| VSNS      | 22  | I                    | Output voltage sense input.                                                                                         |
| Power PAD |     |                      | Connect to system ground by multiple vias.                                                                          |

(1) I = Input, O = Output, P = Power, G = Ground

## FUNCTIONAL BLOCK DIAGRAM



## TYPICAL CHARACTERISTICS

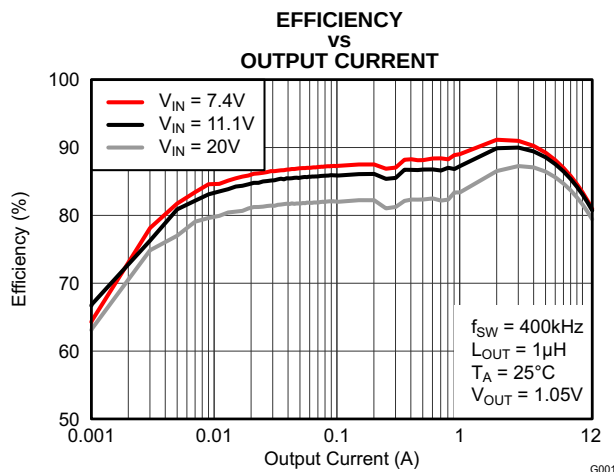


Figure 1.

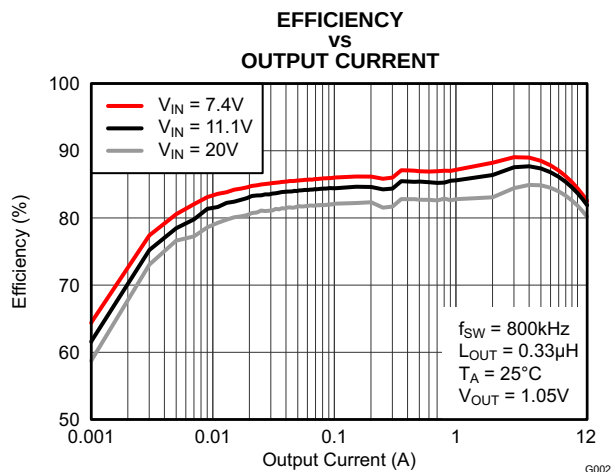


Figure 2.

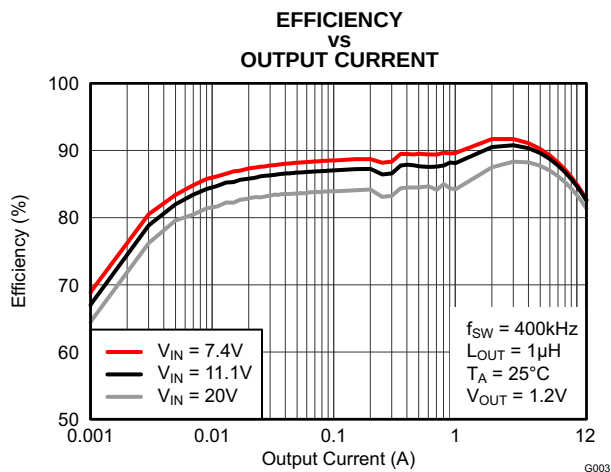


Figure 3.

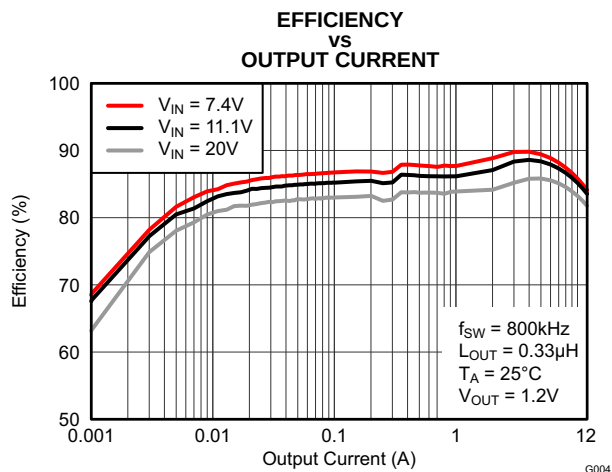


Figure 4.

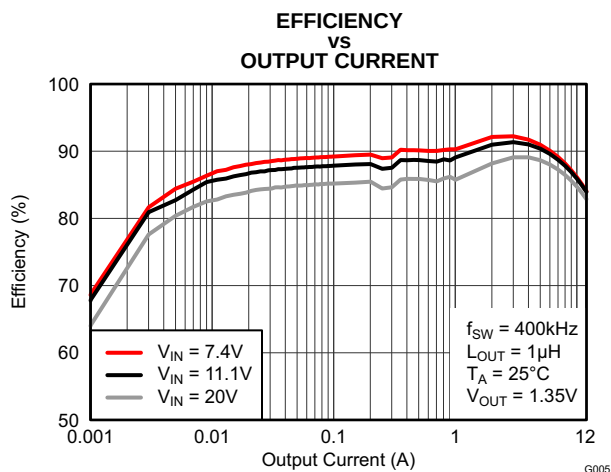


Figure 5.

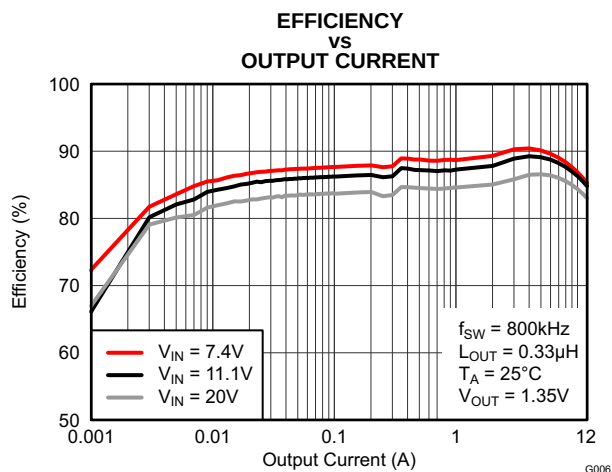
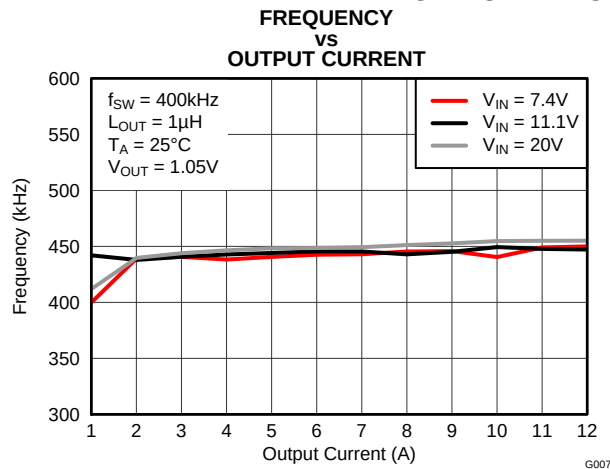
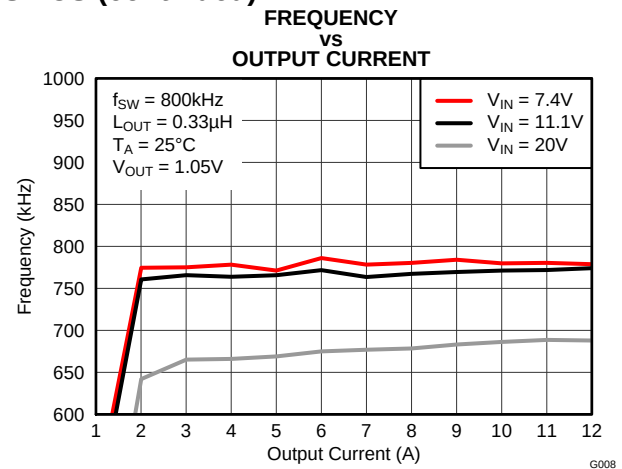
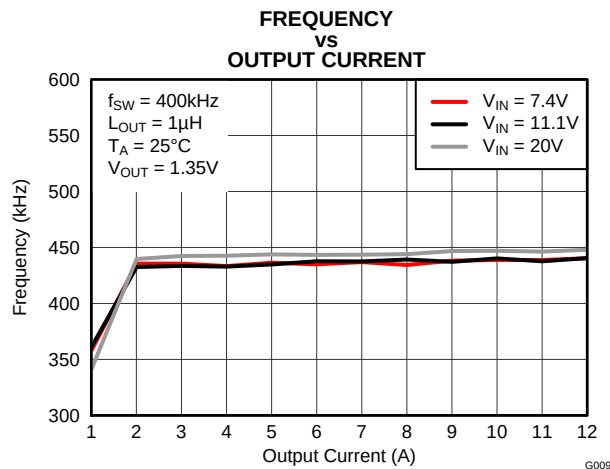
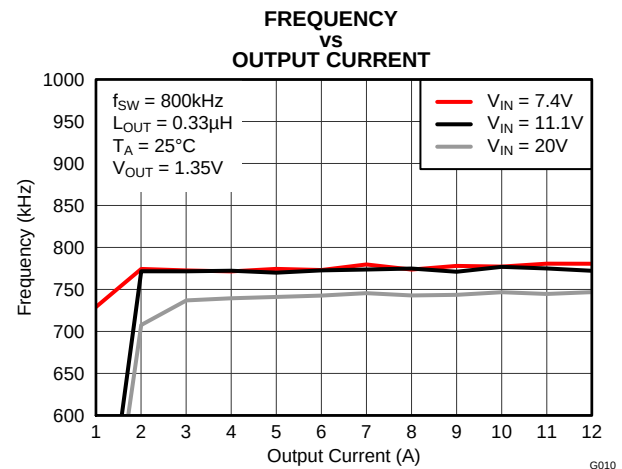
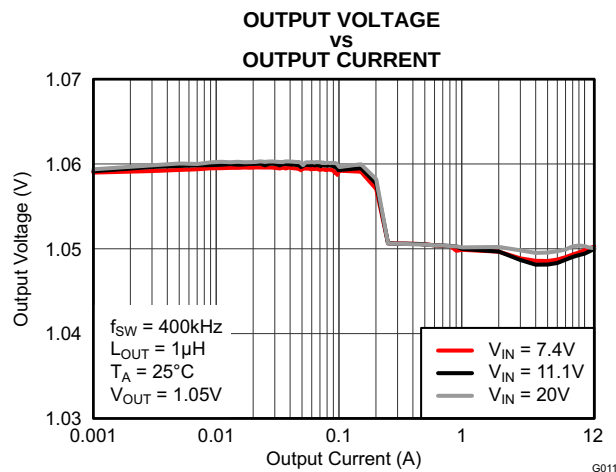
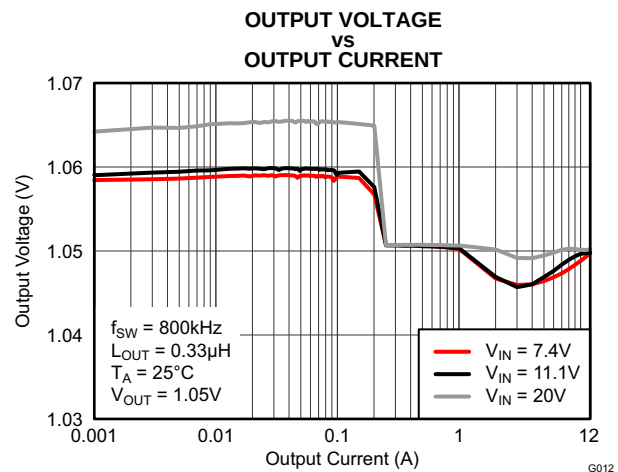


Figure 6.

**TYPICAL CHARACTERISTICS (continued)****Figure 7.****Figure 8.****Figure 9.****Figure 10.****Figure 11.****Figure 12.**

## TYPICAL CHARACTERISTICS (continued)

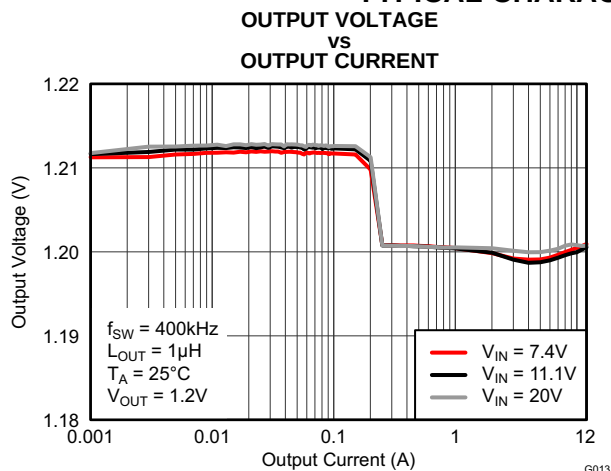


Figure 13.

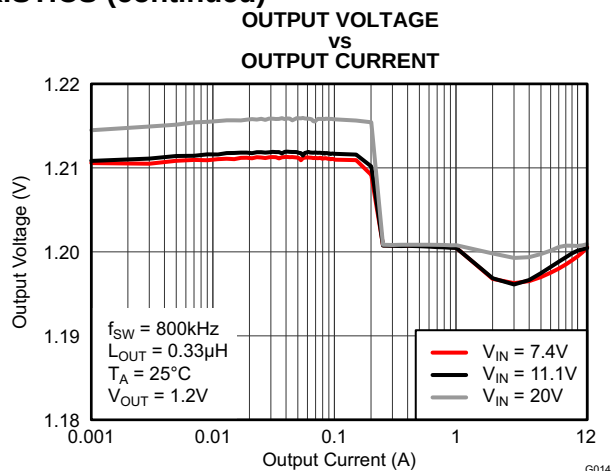


Figure 14.

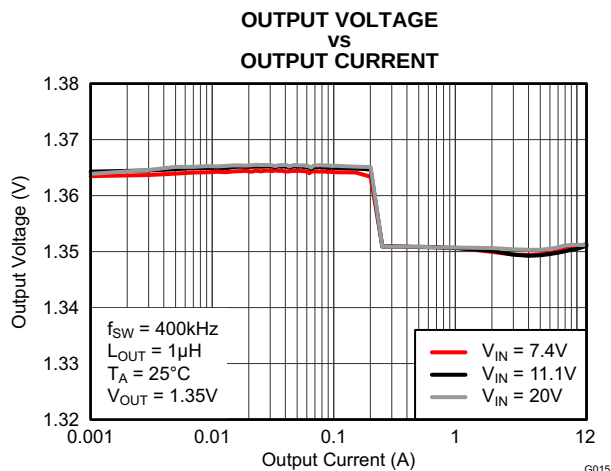


Figure 15.

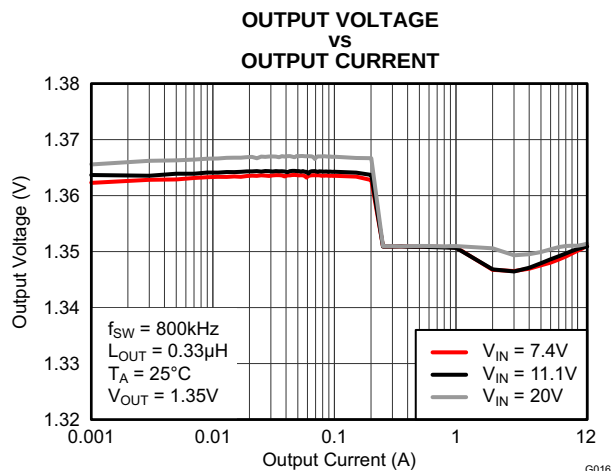


Figure 16.

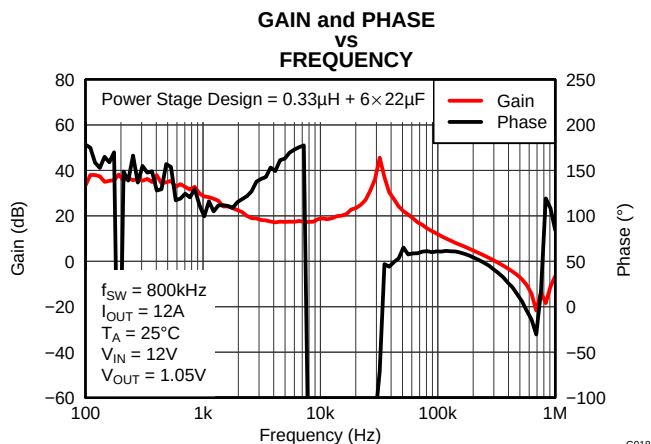


Figure 17.

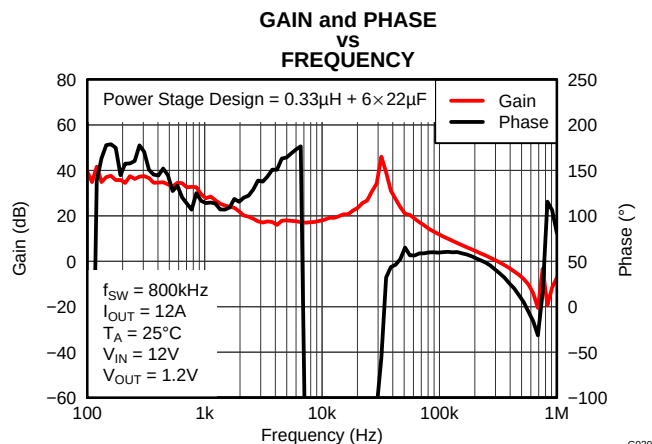


Figure 18.

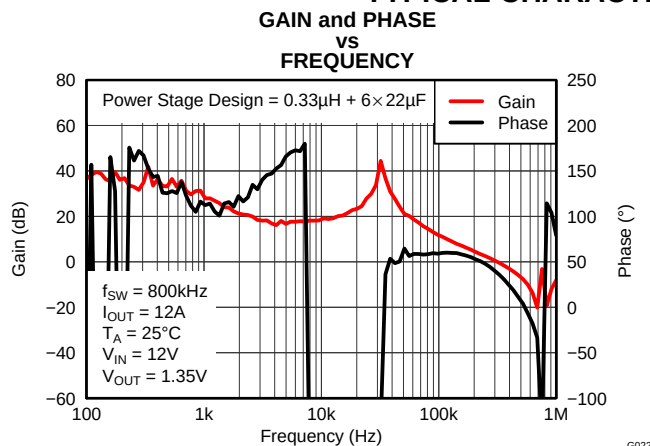
**TYPICAL CHARACTERISTICS (continued)**

Figure 19.

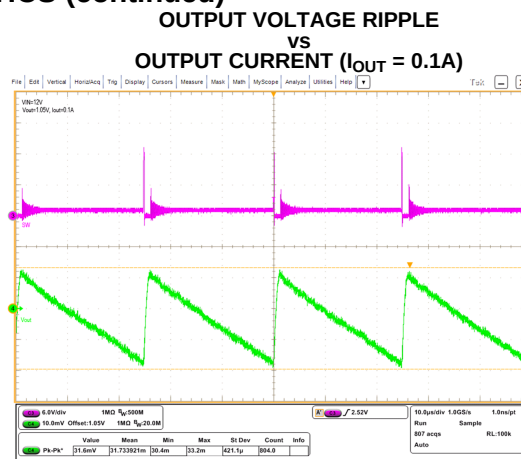


Figure 20.

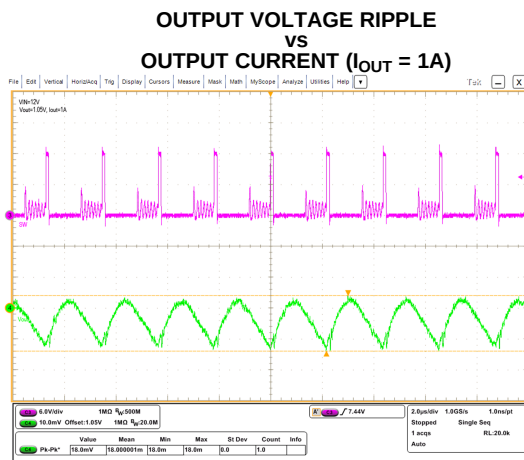


Figure 21.

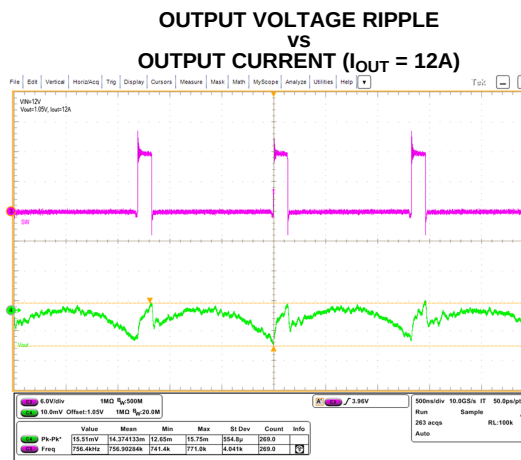


Figure 22.

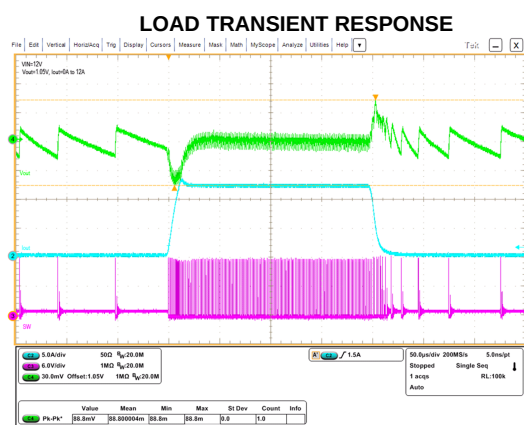


Figure 23.

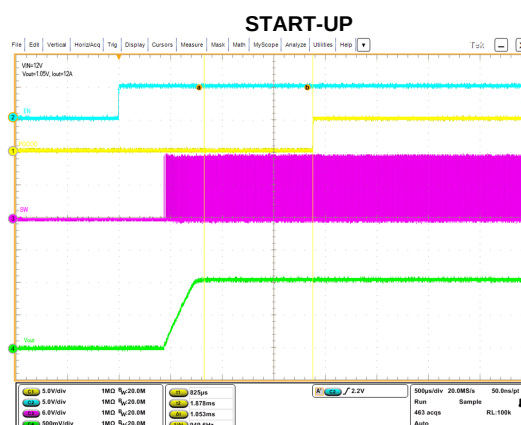


Figure 24.



## TYPICAL CHARACTERISTICS (continued)

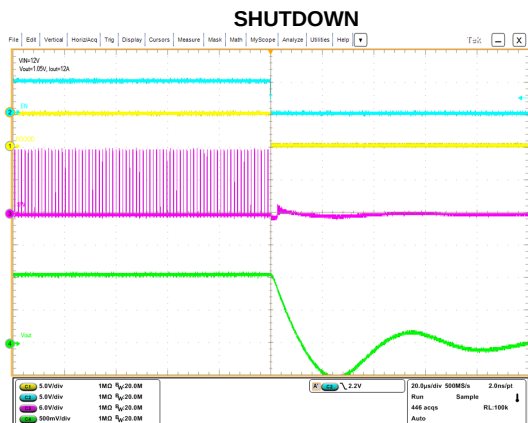


Figure 25.

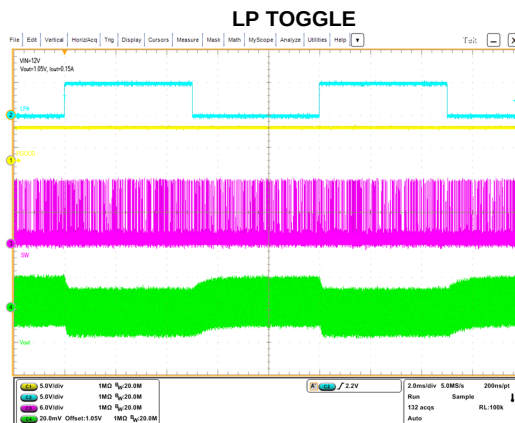


Figure 26.

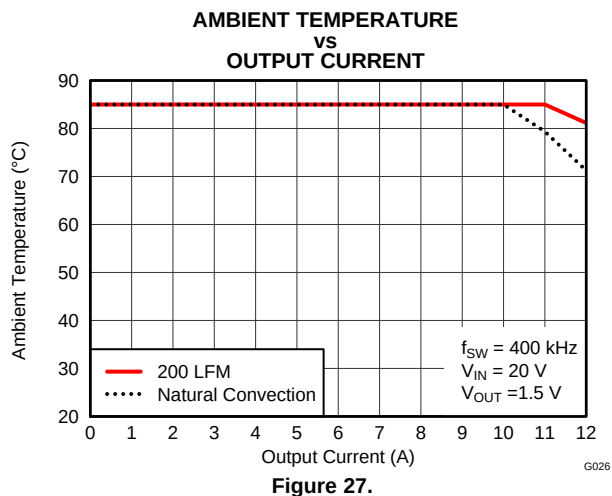


Figure 27.

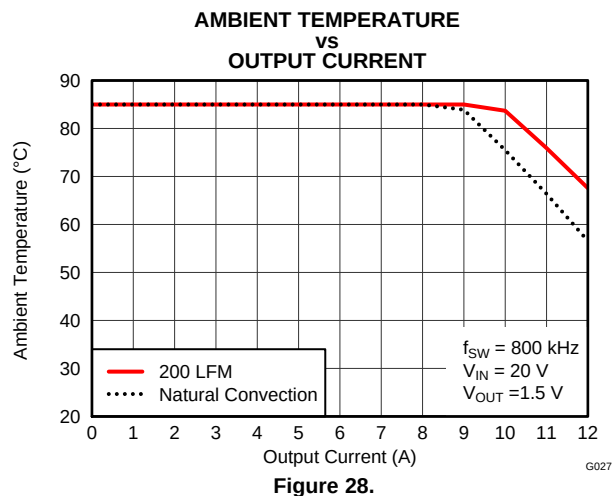


Figure 28.

## APPLICATION INFORMATION

### Functional Overview

The TPS51367 is a 12-A, integrated FET synchronous step-down converter with differential voltage feedback support.

It uses adaptive on-time D-CAP2 for compensation-less stable loop operation in POSCAP, POSCAP/MLCCs and all MLCCs output capacitor configurations.

TPS51367 automatically operates in discontinuous mode to optimize light-load efficiency. A 400-kHz and an 800-kHz switching frequency enables optimization of the power train for cost, size and efficiency performance of the design. The key feature of the TPS51367 is its ULQ™ mode to enable low-bias current (100  $\mu$ A in low power mode, enabled by LP#). This feature is extremely beneficial for long battery life in system standby mode.

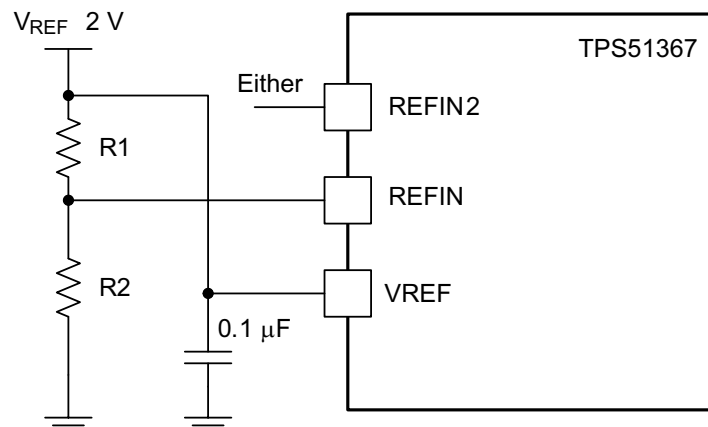
### VREF, REFIN, REFIN2 and Output Voltage

This device provides a 2.0-V, accurate voltage reference from the VREF pin. This output has a 300- $\mu$ A sourcing current capability to drive voltage setpoint reference through a voltage divider circuit as shown in [Figure 29](#). To ensure higher overall system voltage accuracy, the sum of the total resistance from VREF to GND should be designed to be more than 67 k $\Omega$ . A MLCC capacitor with a value of 0.1 $\mu$ F or larger should be attached close to the VREF pin. The voltage setpoint range supported by this device is between 0.6 V and 2.0 V.

This device also supports resistor-less fixed voltage operation by the use of both REFIN and REFIN2 pins. [Table 1](#) lists all the possible fixed voltage configurations by the REFIN and REFIN2 pin. The TPS51367 detects the state of both REFIN and REFIN2 during the initial startup and decides the output voltage setpoint for the operation.

**Table 1. REFIN and REFIN2 Pin Settings**

| VOLTAGE (V)                     |                                   | V <sub>OUT</sub> OUTPUT VOLTAGE (V) |
|---------------------------------|-----------------------------------|-------------------------------------|
| REFIN PIN (V <sub>REFIN</sub> ) | REFIN2 PIN (V <sub>REFIN2</sub> ) |                                     |
| GND                             | GND                               | 1.05                                |
| FLOAT                           | GND                               | 1.2                                 |
| GND                             | FLOAT                             | 1.5                                 |
| FLOAT                           | FLOAT                             | 1.35                                |
| Resistor dividers               | Either GND or FLOAT               | Adjustable from 0.6 to 2.0          |



**Figure 29. Setting the Output Voltage**

## PWM Operation

TPS51367 employs DCAP2 mode operation. It uses an internal phase compensation network ( $R_{C1}$ ,  $R_{C2}$ ,  $C_{C1}$ ,  $C_{C2}$  and gain) to work with very low ESR output capacitors such as multi-layer ceramic capacitor (MLCC). The role of such network is to sense and scale the current ripple component of the output inductor current information and then use it in conjunction with the voltage feedback signal to achieve loop stability of the converter.

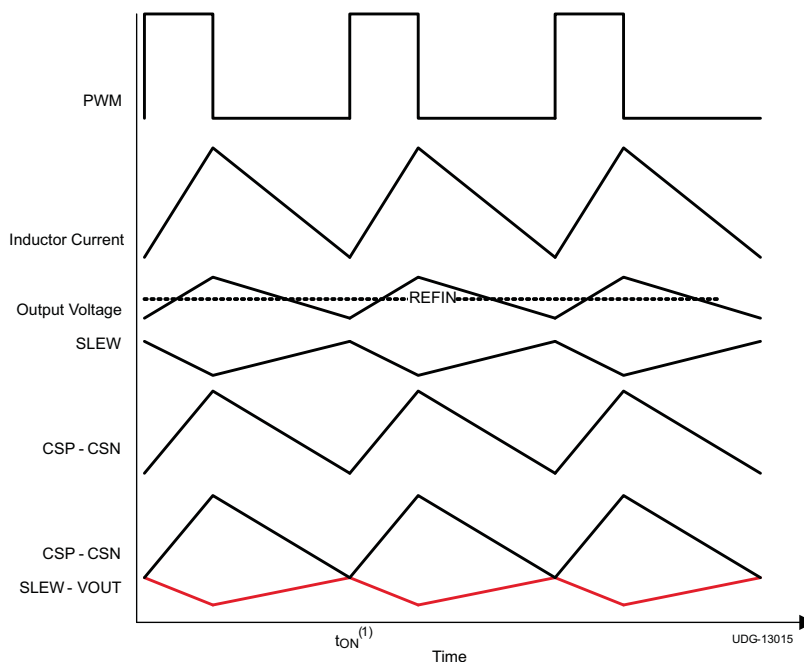
The transconductance ( $g_M$ ) amplifier and SLEW capacitor ( $C1$ ) forms an integrator. The output ripple voltage generated is inversed and averaged by this integrator. The AC information is superimposed onto otherwise DC information and forms a reference voltage at the input of the PWM comparator. As long as the integrator time constant is much larger than the inverse of the loop crossover frequency, the AC component is negligible.

$$\frac{g_M}{(2\pi \times C1)} \leq \frac{f_0}{10}$$

where

- $g_M$  is 60  $\mu S$
  - $f_0$  is 1/3 or 1/4 of the switching frequency ( $f_{sw}$ )
- (1)

The voltage difference ( $V_{SLEW} - V_{SNS}$ ) is then compared to the  $G \times (CSP - CSN)$  (see Figure 31) voltage at the PWM comparator inputs. The PWM comparator creates a SET signal to turn on the high-side MOSFET during each cycle when the current level falls below the loop demand (see Figure 30).



**Figure 30. On-Time Waveforms** <sup>(1)</sup>

(1) ON time is initiated by (VOUT-SLEW) and (CSP-CSN) crossover

The device operates at one distinct switching frequencies, 800 kHz. The switching frequency is configured by MODE pin for this converter operation (see Table 2). For stable operation of the buck converter, it is generally recommended to have a unity gain crossover ( $f_0$ ) of 1/4 or 1/3 or the switching frequency. (see Table 2).

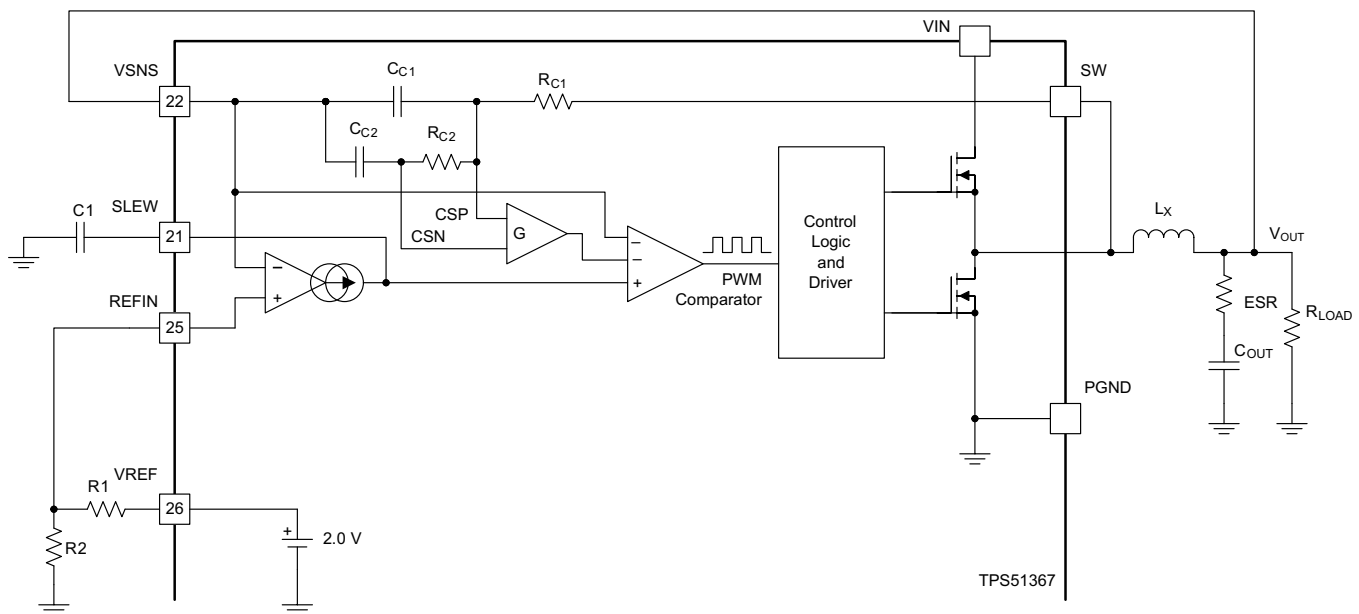
**Table 2. Mode and Recommended Frequency Settings**

| MODE  | FREQUENCY (kHz)     |     |                        |
|-------|---------------------|-----|------------------------|
|       | CROSSOVER ( $f_0$ ) |     | SWITCHING ( $f_{sw}$ ) |
|       | MIN                 | MAX |                        |
| GND   | 100                 | 133 | 400                    |
| FLOAT | 200                 | 267 | 800                    |

Given the range of the recommended unity gain frequency, the power stage design is flexible, as long as the following equation is satisfied.

$$f_{LC} = \frac{1}{2\pi \times \sqrt{L_{OUT} \times C_{OUT}}} \leq \frac{1}{10} \times f_0 \quad (2)$$

Operating in D-CAP2 mode, the overall loop response is dominated by the internal phase compensation network. The compensation network is designed to have two identical zeros at 8 kHz (800-kHz operation) in the frequency domain, which serves the purpose of splitting the LC double pole into one low frequency pole (same as the L-C double pole) and one high-frequency pole (greater than the unity gain crossover frequency).

**Figure 31. Simplified Architecture Illustrating DCAP2 Mode**

## Light-Load Operation

The mandatory light load operation for TPS51367 is referred to as auto skip. In auto-skip mode, the control logic automatically reduces its switching frequency to improve light load efficiency. To achieve this intelligence, a zero crossing detection comparator is used to prevent negative inductor current by turning off the low side FET when the SW crossing zero is detected. The equation below shows the boundary load condition of this skip mode and continuous conduction operation.

$$I_{LOAD(LL)} = \frac{(V_{IN} - V_{OUT})}{2 \times L_X} \times \frac{V_{OUT}}{V_{IN}} \times \frac{1}{f_{SW}} \quad (3)$$

## Power Sequences: Soft-Start and Power Good

Prior to asserting EN high, the power stage conversion voltage and V5IN voltage should be up and running. When EN is asserted high, TPS51367 provides soft start operation to suppress in-rush current during startup. The soft start action is achieved by an internal SLEW current of 10  $\mu$ A (typ) sourcing into a small external MLCC capacitor connected from SLEW pin to GND.

Use [Equation 4](#) to determine the soft-start timing.

$$t_{SS} = C_{SLEW} \times \frac{V_{OUT}}{I_{SLEW}}$$

where

- $C_{SLEW}$  is the soft-start capacitance
  - $V_{OUT}$  is the output voltage
  - $I_{SLEW}$  is the internal, 10- $\mu$ A current source
- (4)

The TPS51367 includes a PGOOD open drain output. During the startup, once the output voltage is slewing up within –8% of the final setpoint target, the PGOOD becomes asserted after 1.5 ms of delay from the end of the soft-start period. During the operation, if the output voltage rises beyond 120% (typ) of the setpoint, the PGOOD pin becomes immediately de-asserted without hysteresis. Re-asserting the PGOOD pin requires either resetting either the V5IN pin or the EN pin. If the output voltage falls below 68% (typ) of the setpoint, the PGOOD pin becomes immediately de-asserted without hysteresis. Re-asserting the PGOOD pin requires resetting either the V5IN pin or the EN pin.

## Fault Protection

### Overcurrent Limit

TPS51367 integrates both high side and low side FETs to support a maximum DC current of 12-A operation. The current sensing method employed for over current limit is to monitor the SW node during the “ON” state of the low side FET for each switching cycle. TRIP pin is used to program one of the two current limits for TPS51367 operation (see [Table 3](#)). When the overcurrent limit is detected, the converter does not allow the next “ON” cycle for the high side FET until the overcurrent limit is no longer reached. This ensures the safe operation of the converter. And when the overcurrent limit condition persists, the current to the load exceeds the current to the output capacitors, the output voltage tends to fall. When the output voltage falls below the undervoltage protection threshold, the converter latch shut down.

**Table 3. TRIP Pin Settings**

| TRIP  | TYPICAL OCL<br>LIMIT $I_{OCL}$ (A) |
|-------|------------------------------------|
| GND   | 8                                  |
| 5V    | 12                                 |
| FLOAT | 16                                 |

### Negative Overcurrent Limit

TPS51367 is also protected by the negative over current limit. Both positive and negative current limit is programmed by the TRIP pin. Negative current limit level is the same as that of positive current limit level (see [Table 3](#)). During the normal converter operation, negative current is not allowed due to the mandatory light load operation for this device (Auto Skip). It is during the OOB or OVP operation, negative overcurrent might be engaged.

### Out-of-Bounds Operation (OOB)

When the output voltage rises to 8% above the target value, the out-of-bound operation starts. During the OOB operation, the controller operates in forced PWM-only mode by turning on low side FET. Turning on the low side FET beyond the zero inductor current can quickly discharge the output capacitor thus causing  $V_{OUT}$  to fall quickly towards setpoint. During the operation, the cycle by cycle negative current limit is also activated to ensure the safe operation of the internal FETs.

### Overvoltage Protection (OVP) and Undervoltage Protection (UVP)

When the output voltage rises to a level 20% (typ) higher than the setpoint voltage, an overvoltage condition is present. When a 0-V event is detected, the converter turns off the high side FET and turns on the low side FET. The operation continues until the cycle by cycle negative current limit is reached and low side FET is turned off and high side FET is turned on, for a minimum on-time. After the minimum on-time expires, the high side FET is driven off and low side FET is driven on again until negative current limit is reached or  $V_{OUT}$  is discharged to 0 V. When the  $V_{OUT}$  is discharged to 0 V, both high-side and low-side FETs are latched off. An OVP fault requires the V5IN voltage to fall below POR threshold or EN reset to clear.

### Undervoltage Protection (UVP)

The undervoltage protection (UVP) is set when the  $V_{OUT}$  voltage falls below 68% (typ) of the setpoint voltage for 1msec or longer. In this fault condition, the converter turns off both high-side and low-side FETs. The UVP function is enabled after 1.4 ms of soft start completion. An UVP fault requires 5-V UVLO or EN reset.

### V5IN Undervoltage Lockout (UVLO) Protection

TPS51367 has a 5-V supply undervoltage lockout protection (UVLO) threshold. When the V5IN voltage is lower than UVLO threshold voltage,  $V_{out}$  is shut off. This is a non-latch protection.

### Power-On-Reset (POR)

To prevent single rail supply voltage brown-out due to output OV condition, when the output voltage is shut down due to OVP fault, Power-on-Reset (POR) on V5IN is implemented. To reset OVP fault, V5IN voltage must fall below POR threshold voltage of 1.7 V (typ) or EN reset to clear.

### Thermal Shutdown

TPS51367 includes an internal temperature monitor. If the die temperature exceeds the threshold (published in the EC table of this datasheet), the converter will be shutdown. This is a non-latch protection and the operation is restarted with soft-start sequence when the device temperature is reduced by the hysteresis.

## DESIGN PROCEDURE

### Introduction

The simplified design procedure is done for a VCCIO rail for Intel platform application using TPS51367.

#### Step One: Determine the system specifications.

The VCCIO rail requirements provide the following key parameters:

- $V_{OUT} = 1.05\text{ V}$
- $I_{CC(max)} = 6\text{ A}$
- $I_{DYN(max)} = 4\text{ A}$

#### Step Two: Determine the power supply design specifications.

The input voltage range and operating frequency are of primary interest. For this example:

- $7.4\text{ V} \leq V_{IN} \leq 19.5\text{ V}$
- $f_{SW} = 800\text{ kHz}$

#### Step Three: Set the output voltage.

TPS51367 supports resistor-less fixed voltage operation by the use of both REFIN and REFIN2 pins (see [Table 1](#)). Grounding both REFIN and REFIN2 pins provides a 1.05-V fixed output setpoint.

#### Step Four: Determine inductance value and choose inductor.

Smaller values of inductor have better transient performance and smaller physical size but higher ripple and lower efficiency. Higher values have the opposite characteristics. It is common practice to limit the ripple current to 25% to 50% of the maximum current. For this example, use 30% as a starting point.  $I_{L(P-P)} = 6\text{ A} \times 0.30 = 1.8\text{ A}$ . For a switching frequency of 800 kHz, maximum 19.5-V input and 1.05-V output.

$$L = \frac{V \times dT}{I_{P-P}} = \frac{(V_{IN} - V_{OUT}) \times \left( \frac{V_{OUT}}{f_{SW} \times V_{IN}} \right)}{I_{P-P}} = \frac{(19.5\text{ V} - 1.05\text{ V}) \times \left( \frac{1.05\text{ V}}{800\text{ kHz} \times 19.5\text{ V}} \right)}{1.8\text{ A}} = 0.68\text{ }\mu\text{H} \quad (5)$$

For this application, a 0.68- $\mu\text{H}$ , 6.8 mm  $\times$  7.3 mm  $\times$  3.0 mm inductor with typical DCR of 4.8 m $\Omega$  and heating current of 16 A is chosen. The Cyntec part number of the inductor is PIMB063T.

#### Step Five: Calculate SLEW capacitance.

The SLEW pin is used to program the soft-start time. During soft-start operation, the current source used to program the SLEW rate is 10  $\mu\text{A}$  (typ). In this design example, the soft-start timing should be target to be in the range of 500  $\mu\text{s}$  to 2 ms. The proper slew rate design minimizes large inductor current perturbation during the startup, thus reducing the possibility of acoustic noise in the system.

$$C_{SLEW} = I_{SLEW} \times \frac{dt}{\Delta V_{OUT}} = 10\text{ nF} \quad (6)$$

- $I_{SLEW} = 10\text{ }\mu\text{A}$ ,
- $dt = t_{SS} = 1\text{ ms}$
- $\Delta V_{OUT} = 1.05\text{ V}$

#### Step Six: Select the proper OCL.

There are two options for the over current limit (see [Table 3](#)). For this application example, because  $I_{CC(max)} = 6\text{ A}$ , the proper OCL level should be set at least 30% over the  $I_{CC(max)}$  level, which makes the 8-A OCL appropriate for this design. Grounding the TRIP pin achieves this effect.

#### Step Seven: Determine the output capacitance.

The amount of the output capacitance needed for this design is both a function of loop stability and of transient requirement.

### Stability Considerations

The switching frequency of the design example is 800 kHz (which is set by the MODE pin, see [Table 3](#)). For D-CAP2 mode operation, it is generally recommended to have a unity gain crossover ( $f_0$ ) of less than 1/4 or 1/3 of the switching frequency, which is approximately between 200 kHz and 266 kHz. In this design example, use 1/4.

$$f_0 = \frac{f_{SW}}{4} = 200\text{kHz} \quad (7)$$

Given the range of the recommended unity gain crossover frequency, the power stage design is flexible, as long as the L-C double pole frequency is less than 10% of  $f_0$ .

When the above criteria is met, the internal compensation network provides sufficient phase boost at the unity gain crossover frequency such that the converter is stable with sufficient phase margin (greater than 60 deg.).

When the ESR frequency of the output bulk capacitor is in the vicinity of the unity gain crossover frequency of the loop, additional phase boost can be achieved. This applies to higher ESR output bulk capacitor, POSCAP and SPCAP.

When the ESR frequency of the output capacitor is beyond the unity gain crossover frequency of the control loop, no additional phase boost is achieved. This applies to low or ultra low ESR output capacitor, such as MLCCs.

For this application example, consider only all MLCCs for output capacitors. Based on [Equation 3](#) and [Equation 7](#), the minimum capacitance for stable operation is calculated to be 110  $\mu\text{F}$ .

### Transient considerations

- $I_{DYN(max)} = 4\text{ A}$
- $di/dt = 2.5\text{ A}/\mu\text{s}$
- $V_{OUT}$  deviation =  $\pm 3\%$  for the given transient

Use [Equation 8](#) and [Equation 9](#) to estimate the amount of capacitance needed for a given dynamic load/release.

$$C_{OUT(min\_under)} = \frac{L \times (\Delta I_{LOAD(max)})^2 \times \left( \frac{V_{OUT} \times t_{SW}}{V_{IN(min)}} + t_{MIN(off)} \right)}{2 \times \Delta V_{LOAD(insert)} \times \left( \left( \frac{V_{IN(min)} - V_{OUT}}{V_{IN(min)}} \right) \times t_{SW} - t_{MIN(off)} \right) \times V_{OUT}} \quad (8)$$

$$C_{OUT(min\_over)} = \frac{L_{OUT} \times (\Delta I_{LOAD(max)})^2}{2 \times \Delta V_{LOAD(release)} \times V_{OUT}} \quad (9)$$

Based on these calculation, to meet the transient requirement, the minimum amount of capacitance in this design is 164  $\mu\text{F}$ .

Considering both stability and transient, the minimum capacitance is 164  $\mu\text{F}$ . The design example uses 8, 22- $\mu\text{F}$  capacitors with minor consideration of the MLCC derating for both DC and AC effect.

### Step Eight: Select decoupling and peripheral components.

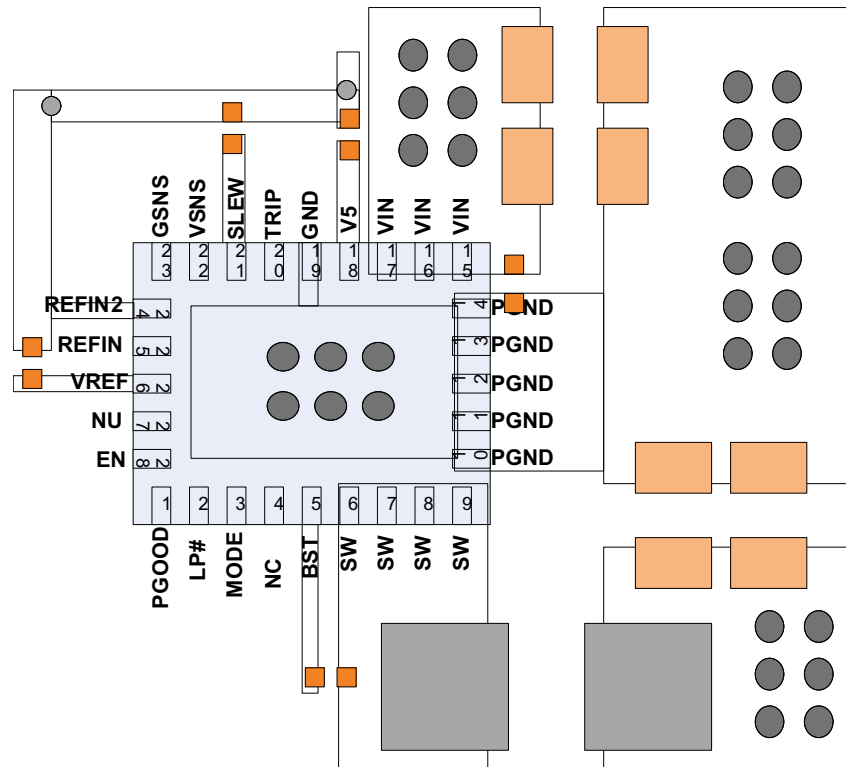
For the TPS51367, peripheral capacitors use the following minimum values of ceramic capacitance. X5R or better temperature coefficient is recommended. Tighter tolerance and higher voltage rating are always appropriate.

- $V_{5IN}$  decoupling  $\geq 2.2\text{ }\mu\text{F}$ ,  $\geq 10\text{ V}$
- $V_{REF}$  decoupling  $0.1\text{ }\mu\text{F}$  to  $1\text{ }\mu\text{F}$ ,  $\geq 4\text{ V}$
- Bootstrap capacitor  $\geq 0.1\text{ }\mu\text{F}$ ,  $\geq 10\text{ V}$
- Pull-up resistors on PGOOD, 100 k $\Omega$

### Step Nine: Layout guidelines.

[Figure 32](#) applies to the layer where device is situated. Additional reinforcement of VIN, PGND, and VOUT through vias are always recommended.





**Figure 32. TPS51367 Design Layout**

Input capacitors, output capacitors, and the output inductor are the power components and should be placed on one side of the PCB. Small signal components can be placed on the same side of the PCB with proper ground isolation or the opposite side with at least one inner ground plane in between, depending on the system/motherboard design requirement.

All sensitive analog traces and components such as VSNS, GSNS, SLEW, VREF, REFIN and REFIN2 should be placed away from the high voltage switching node, such as SW and BST to avoid switching noise coupling. Use internal layer(s) as ground plane(s) and shield feedback traces from power traces.

VSNS can be connected directly to the output voltage sense point at the load device or the bulk capacitor at the converter side. Connect GSNS to ground return at the general ground plane/layer. VSNS and GSNS can be used for the purpose of remote sensing across the load device, however, ensure to minimize the routing trace length to prevent excess noise injection into the sense lines.

In order to effectively remove heat from the package, prepare the thermal land and solder to the package thermal pad. Wide trace of the component-side copper, connected to this thermal land, helps to dissipate the heat. Numerous vias (at least 6) with a 0.3-mm diameter connected from the thermal land to the internal/solder side ground plane(s) should be used to help dissipation.

## REFERENCE DESIGNS

This section describes three typical application circuits using the TPS51367.

### Design 1

This design is a VCCIO application with an output voltage of 1.05 V, maximum processor current ( $I_{CC(max)}$ ) of 6 A, an OCL of 8 A and a switching frequency of 800 kHz.

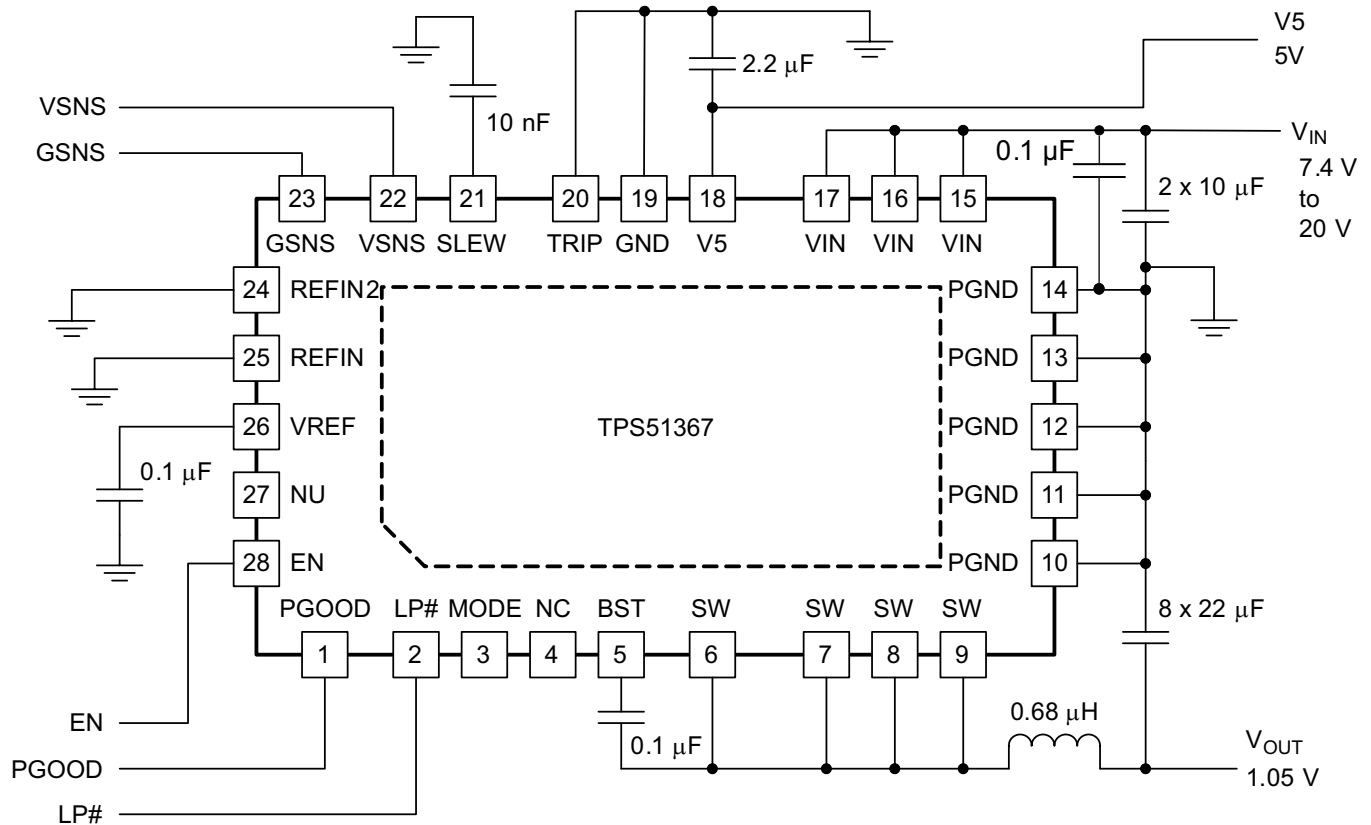


Figure 33. Design 1: Application Schematic

Table 4. Design 1: List of Materials

| REFERENCE DESIGNATOR | QTY | SPECIFICATION   | MANUFACTURER | PART NUMBER       |
|----------------------|-----|-----------------|--------------|-------------------|
| C <sub>IN</sub>      | 2   | 10 µF, 25 V     | Taiyo Yuden  | TMK325BJ106MM     |
| C <sub>OUT</sub>     | 8   | 22 µF, 6.3 V    | Murata       | GRM21BB30J226ME38 |
| L <sub>OUT</sub>     | 1   | 0.68 µH, 4.8 mΩ | Cyntec       | PIMB063T-R68MS-63 |

## Design 2:

This design is a DDR3L, VDDQ, application with an output voltage of 1.35 V, maximum processor current ( $I_{CC(max)}$ ) of 8 A, an OCL of 12 A, and a switching frequency of 400 kHz.

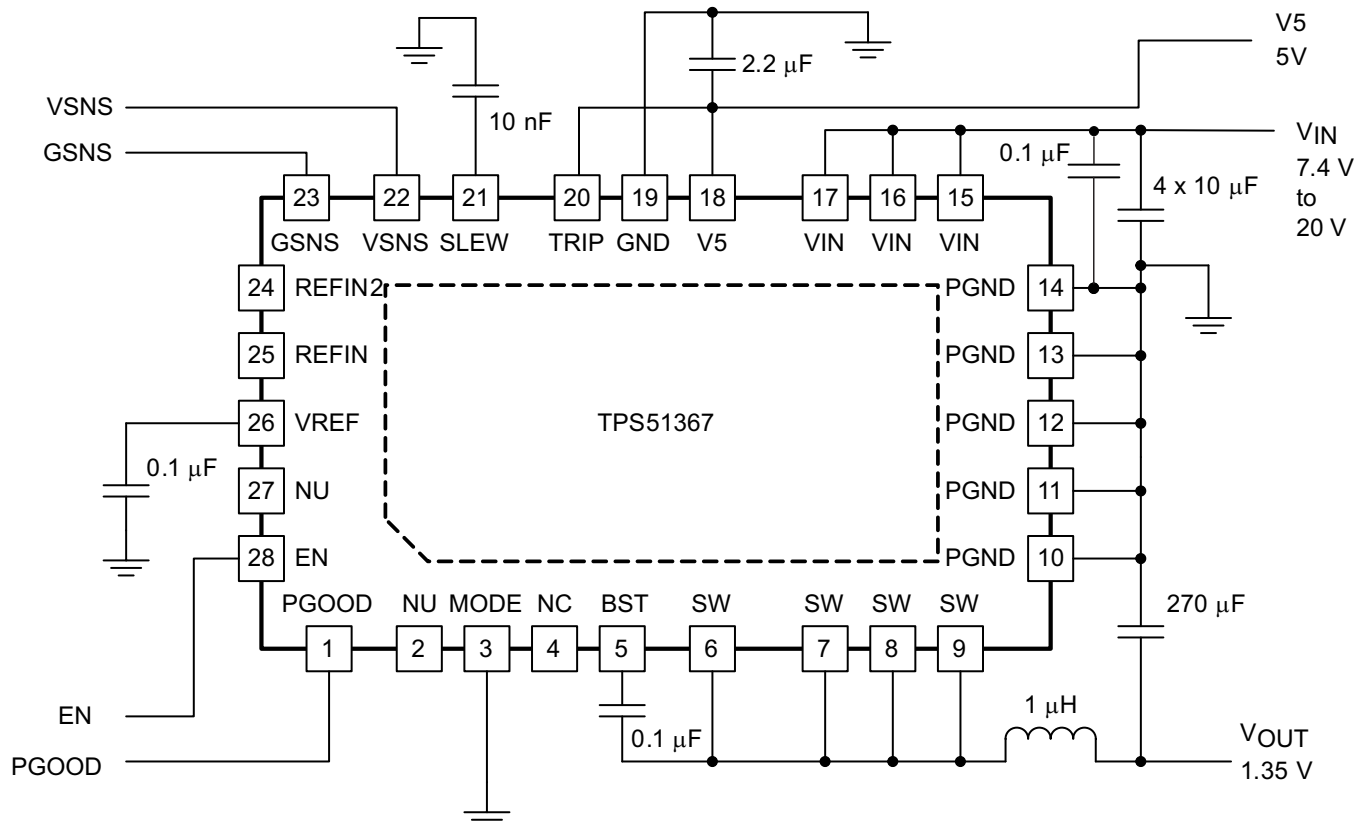


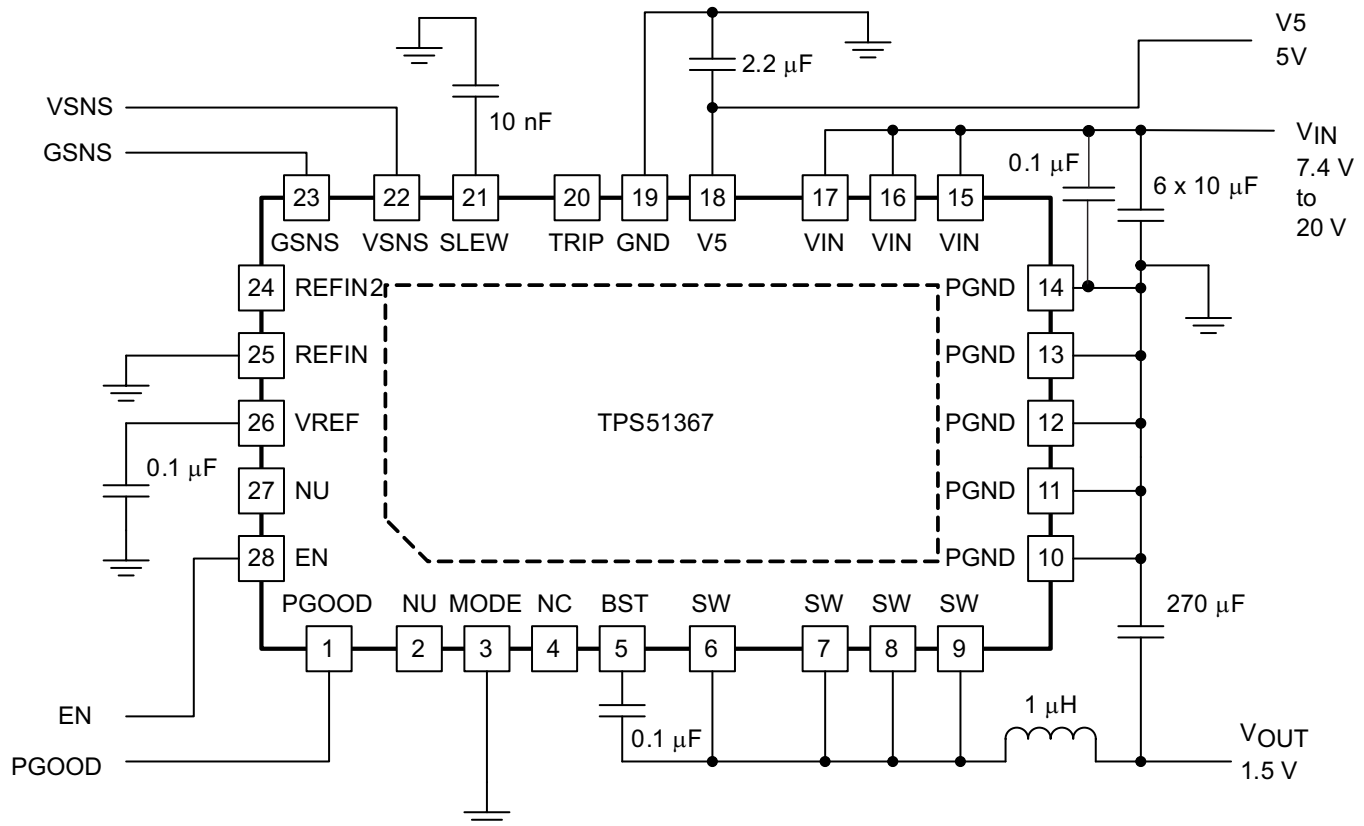
Figure 34. Design 2: Application Schematic

Table 5. Design 2: List of Materials

| REFERENCE DESIGNATOR | QTY | SPECIFICATION | MANUFACTURER | PART NUMBER       |
|----------------------|-----|---------------|--------------|-------------------|
| C <sub>IN</sub>      | 4   | 10 μF, 25 V   | Taiyo Yuden  | TMK325BJ106MM     |
| C <sub>OUT</sub>     | 1   | 270 μF, 2 V   | Panasonic    | 2TPSF270M6E       |
| L <sub>OUT</sub>     | 1   | 1 μH, 6.7 mΩ  | Cyntec       | PCME063T-1R0MS-63 |

**Design 3:**

This design is a DDR3, VDDQ, application with an output voltage of 1.5 V, maximum processor current ( $I_{CC(max)}$ ) of 12 A, an OCL of 16 A, and a switching frequency of 400 kHz.



**Figure 35. Design 3: Application Schematic**

**Table 6. Design 3: List of Materials**

| REFERENCE DESIGNATOR | QTY | SPECIFICATION | MANUFACTURER | PART NUMBER       |
|----------------------|-----|---------------|--------------|-------------------|
| C <sub>IN</sub>      | 6   | 10 µF, 25 V   | Taiyo Yuden  | TMK325BJ106MM     |
| C <sub>OUT</sub>     | 1   | 270 µF, 2 V   | Panasonic    | 2TPSF270M6E       |
| L <sub>OUT</sub>     | 1   | 1 µH, 6.7 mΩ  | Cyntec       | PCME063T-1R0MS-63 |

## REVISION HISTORY

NOTE: Page numbers of current version may differ from previous versions.

| Changes from Original (February 2013) to Revision A                                                                                                                                                                                                                                                                                                                                                                                                                      | Page |
|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------|
| • Added MIN and MAX values to $I_{OCL}$ spec in Elec Char table .....                                                                                                                                                                                                                                                                                                                                                                                                    | 5    |
| • Changed the Functional Block Diagram $V_{REFIN}$ signal line identifier on the UV-detect device from " $V_{REFIN} - 32\%$ " to " $V_{REFIN} - 34\%$ ". Changed signal line identifier on the high-side comparator from " $V_{REFIN} + 8/20\%$ " to " $V_{REFIN} + 20\%$ ". Changed the high-side device symbol from hysteresis to a comparator. Changed signal line identifier on the low-side device from " $V_{REFIN} - 8/32\%$ " to " $V_{REFIN} - 8/34\%$ ". ..... | 8    |
| • Changed <a href="#">Figure 22</a> graph X-axis label from "OUTPUT CURRENT ( $I_{OUT} = 10A$ )" to "OUTPUT CURRENT ( $I_{OUT} = 12A$ )" in Typical Characteristics section. ....                                                                                                                                                                                                                                                                                        | 12   |
| • Added Land pads for a 0.1- $\mu F$ capacitor between VIN and PGND of the TPS51367 Design Layout figure. ....                                                                                                                                                                                                                                                                                                                                                           | 21   |
| • Added a 0.1- $\mu F$ capacitor symbol between VIN and PGND of the Design 1: Application Schematic. ....                                                                                                                                                                                                                                                                                                                                                                | 22   |
| • Changed $L_{OUT}$ inductor part number from PIMB063T to PIMB063T-R68MS-63 in Design 1: List of Materials table. ....                                                                                                                                                                                                                                                                                                                                                   | 22   |
| • Changed text from "LPDDR3" to "DDR3L" in Design 2 description section. ....                                                                                                                                                                                                                                                                                                                                                                                            | 23   |
| • Added 0.1 $\mu F$ capacitor symbol between VIN and PGND in Design 2: Application Schematic figure .....                                                                                                                                                                                                                                                                                                                                                                | 23   |
| • Changed $L_{OUT}$ inductor spec from 1 $\mu H$ , 6.5 m $\Omega$ to 6.7 m $\Omega$ , and part number from PCME063T to PIMB063T-1R0MS-63 in Design 2: List of Materials table. ....                                                                                                                                                                                                                                                                                      | 23   |
| • Changed QTY of $C_{IN}$ from 4 to 6; changed $L_{OUT}$ inductor spec from 1 $\mu H$ , 6.5 m $\Omega$ to 6.7 m $\Omega$ , and part number from PCME063T to PIMB063T-1R0MS-63 in Design 3: List of Materials table. ....                                                                                                                                                                                                                                                 | 24   |

## PACKAGING INFORMATION

| Orderable part number        | Status<br>(1) | Material type<br>(2) | Package   Pins       | Package qty   Carrier | RoHS<br>(3) | Lead finish/<br>Ball material<br>(4) | MSL rating/<br>Peak reflow<br>(5) | Op temp (°C) | Part marking<br>(6) |
|------------------------------|---------------|----------------------|----------------------|-----------------------|-------------|--------------------------------------|-----------------------------------|--------------|---------------------|
| <a href="#">TPS51367RVER</a> | Active        | Production           | VQFN-CLIP (RVE)   28 | 3000   LARGE T&R      | ROHS Exempt | NIPDAU   SN                          | Level-2-260C-1 YEAR               | -10 to 85    | TPS51367            |
| <a href="#">TPS51367RVET</a> | Active        | Production           | VQFN-CLIP (RVE)   28 | 250   SMALL T&R       | ROHS Exempt | NIPDAU   SN                          | Level-2-260C-1 YEAR               | -10 to 85    | TPS51367            |

<sup>(1)</sup> **Status:** For more details on status, see our [product life cycle](#).

<sup>(2)</sup> **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

<sup>(4)</sup> **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

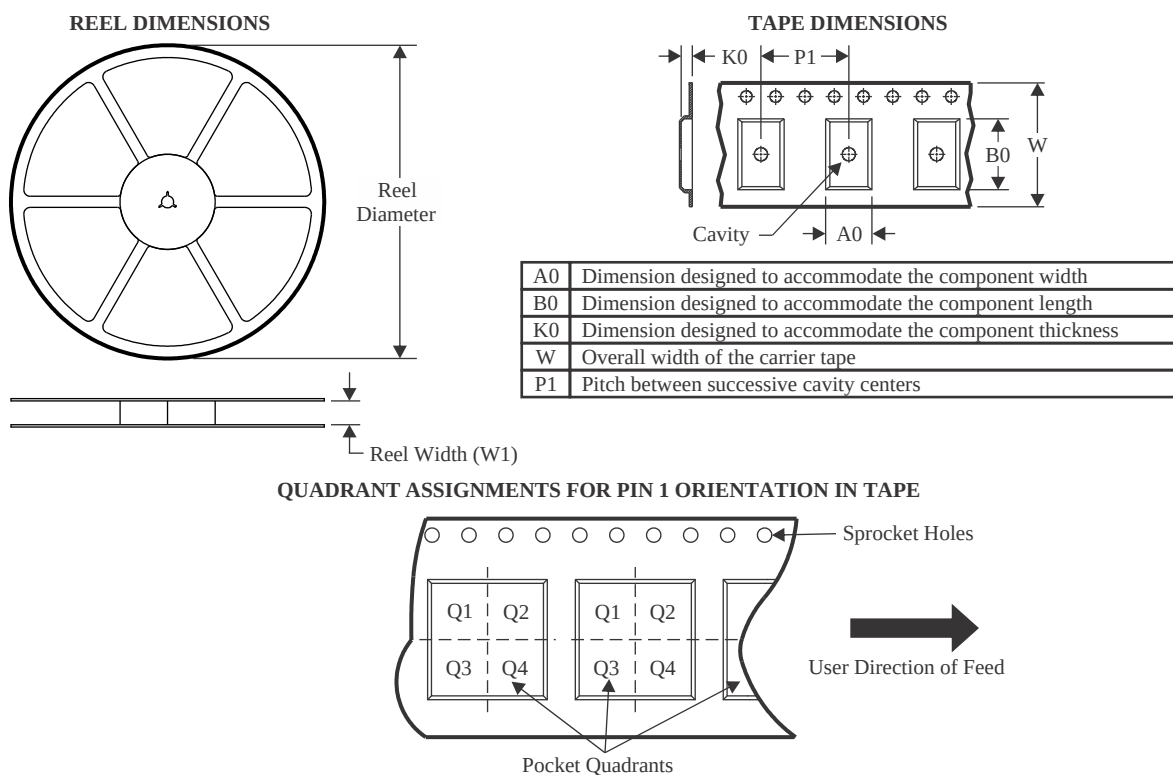
<sup>(6)</sup> **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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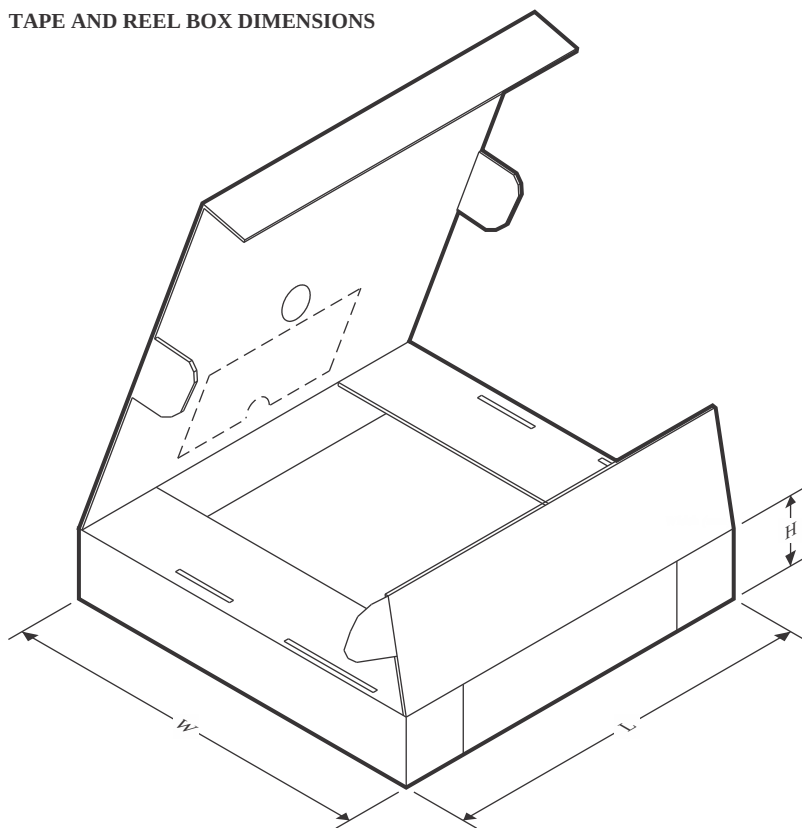
## TAPE AND REEL INFORMATION



\*All dimensions are nominal

| Device       | Package Type | Package Drawing | Pins | SPQ  | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|--------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| TPS51367RVER | VQFN-CLIP    | RVE             | 28   | 3000 | 330.0              | 12.4               | 3.71    | 4.71    | 1.1     | 8.0     | 12.0   | Q1            |
| TPS51367RVET | VQFN-CLIP    | RVE             | 28   | 250  | 180.0              | 12.4               | 3.71    | 4.71    | 1.1     | 8.0     | 12.0   | Q1            |

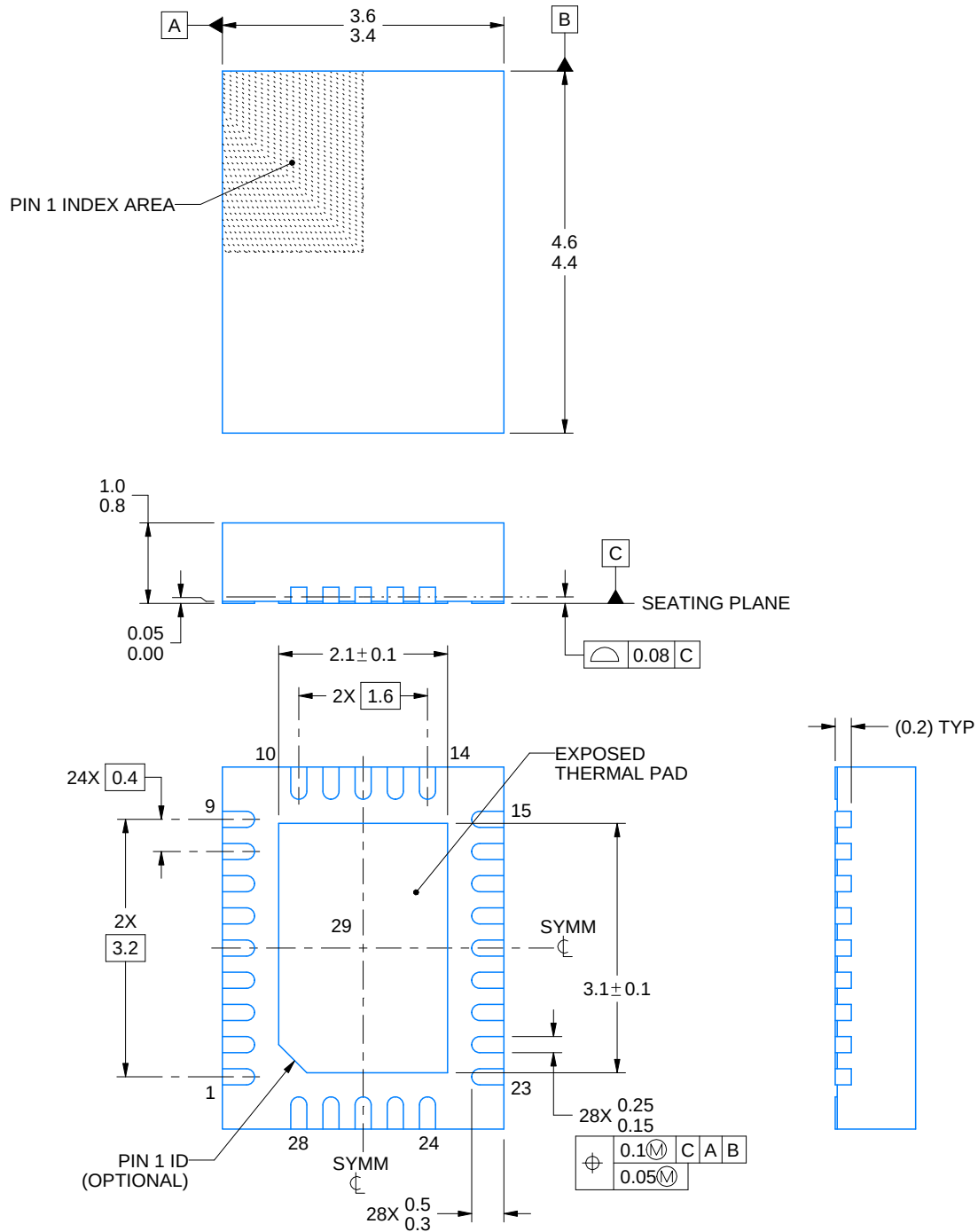
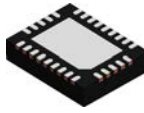
## TAPE AND REEL BOX DIMENSIONS



\*All dimensions are nominal

| Device       | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|--------------|--------------|-----------------|------|------|-------------|------------|-------------|
| TPS51367RVER | VQFN-CLIP    | RVE             | 28   | 3000 | 346.0       | 346.0      | 33.0        |
| TPS51367RVET | VQFN-CLIP    | RVE             | 28   | 250  | 210.0       | 185.0      | 35.0        |





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## NOTES:

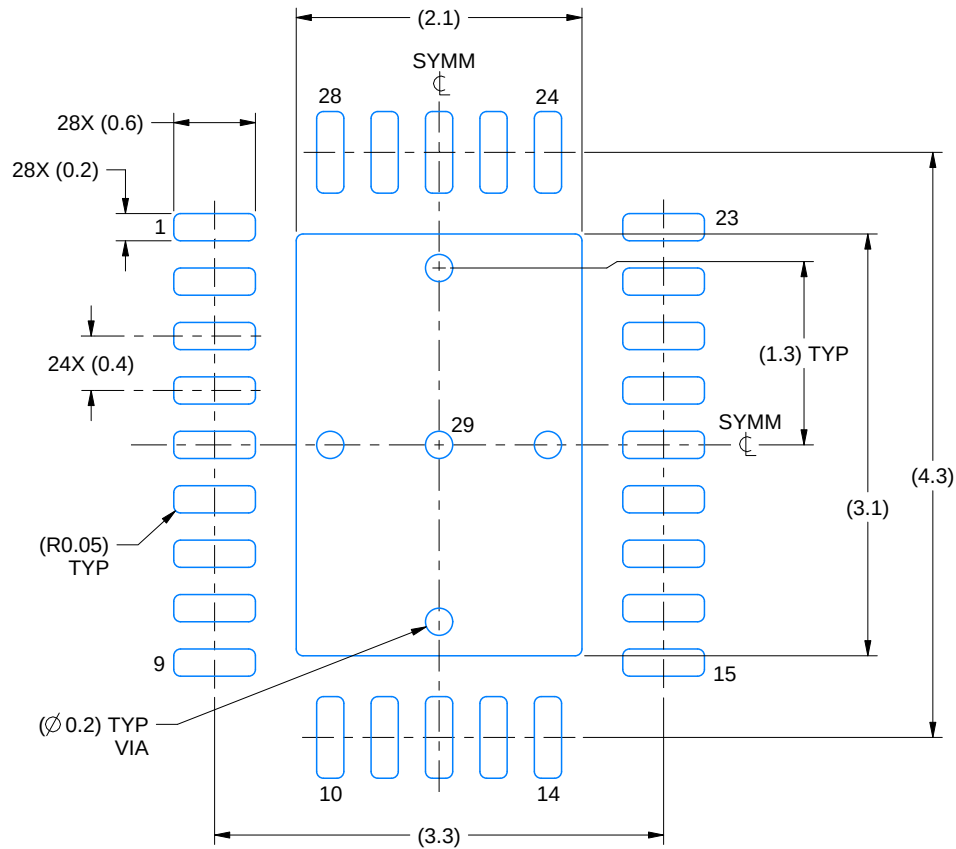
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

# EXAMPLE BOARD LAYOUT

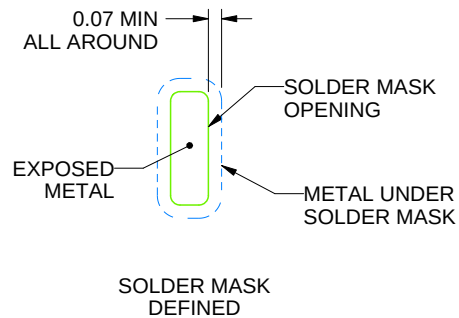
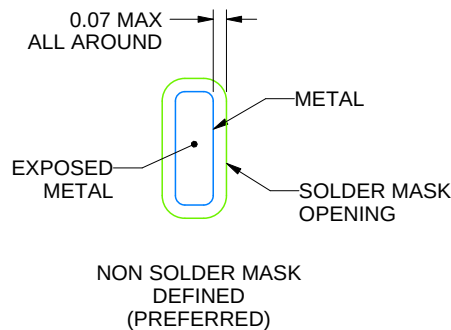
RVE0028A

VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE:18X



SOLDER MASK DETAILS

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NOTES: (continued)

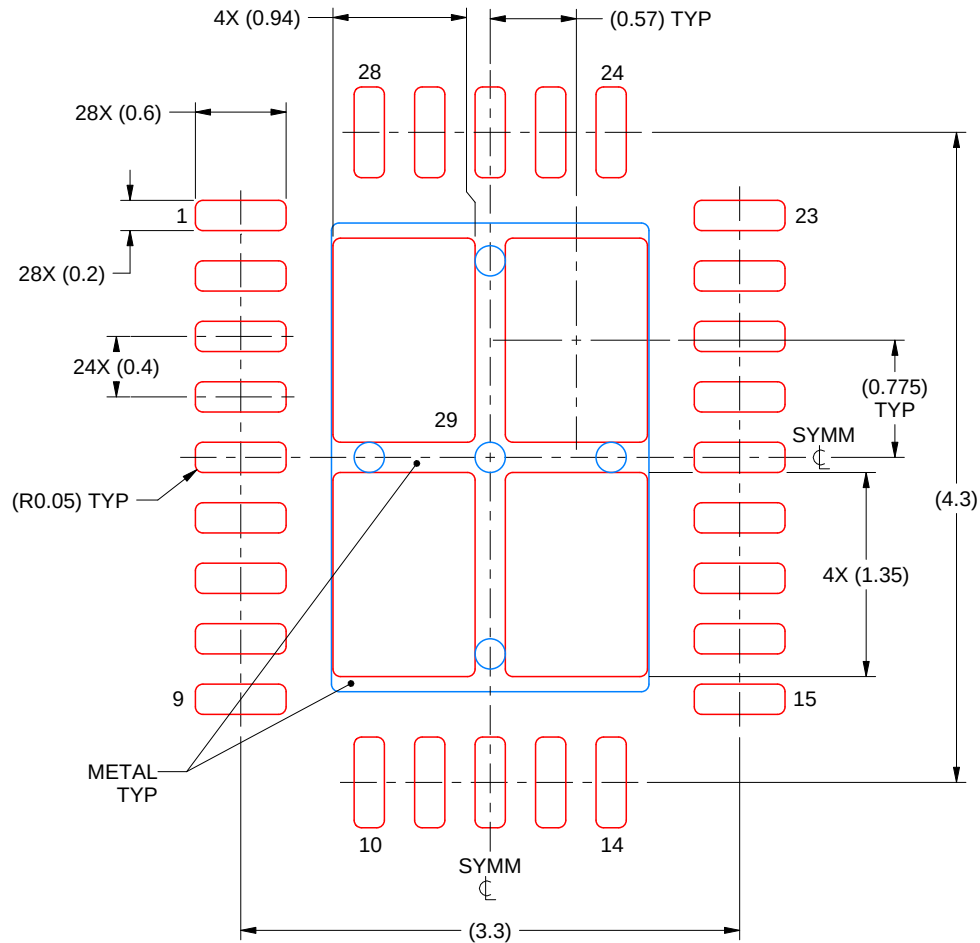
- This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 ([www.ti.com/lit/slue271](http://www.ti.com/lit/slue271)).
- Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

# EXAMPLE STENCIL DESIGN

RVE0028A

VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



**SOLDER PASTE EXAMPLE**  
 BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD 29  
 78% PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE  
 SCALE:20X

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NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

RVE (R-PVQFN-N28)

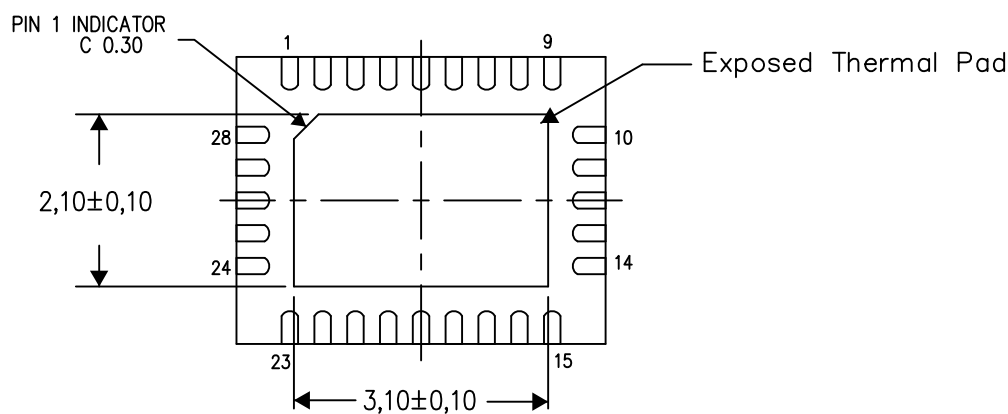
PLASTIC QUAD FLATPACK NO-LEAD

## THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at [www.ti.com](http://www.ti.com).

The exposed thermal pad dimensions for this package are shown in the following illustration.



Bottom View

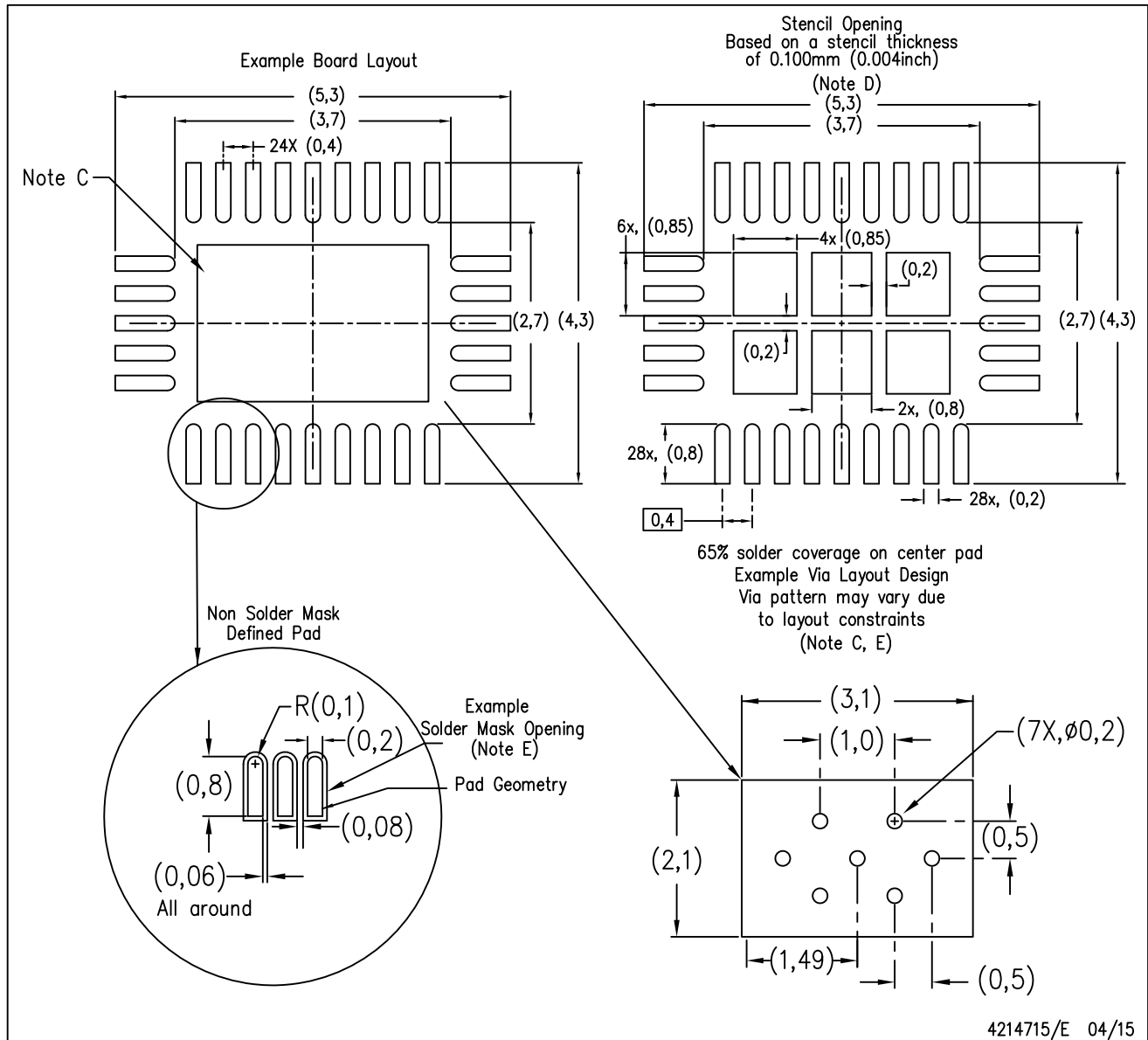
Exposed Thermal Pad Dimensions

4211776/E 04/15

NOTE: All linear dimensions are in millimeters

RVE (R-PWQFN-N28)

PLASTIC QUAD FLATPACK NO-LEAD



4214715/E 04/15

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